



Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY

(An Autonomous Institute affiliated to VTU, Accredited by NAAC with 'A' grade)

BDA Outer Ring Road, Mallathalli, Bengaluru-56

Board Of Studies 2023-24



Approved Scheme and Syllabus of V & VI Semester For 2021 Batch

Submitted by

Department of Electronics and Communication Engineering

> To DEAN (Academic)

			Dr. Ambedka	r Institute of Te	chnology	y, Ben	galu	ru-560	056					
			Outcome Based Education(O	BE) and Choice Ba	sed Cred	it Syste	em (C			EP2020)				
				. Electronics & Com										
			Tentative Scheme	e of Teaching and Exa (Applicable to			from t	he Acad	emic Year	2022-23				
T O	4			(Applicable to	2021 Date	cii)								
	mester				-	75 1		/ ***		1		• .•		
Sl. No.	Course Category	Course Code	Course Title	Teaching Department	L	Teac	P	rs/ Week	Total	Duration	Exan CIE	ination SEE	Total	Credits
	Category			Department	L		<u> </u>	5	Ioun	(Hrs)	Marks	Marks	Marks	
1	РСС	21ECT501	Digital Communication	ECE	3	0	0			3	50	50	100	3
2	IPCC	21ECT502	Microprocessor & Microcontrollers	ECE	3	0	2		3	3	50	50	100	4
3	РСС	21ECT503	Computer Communication Networks	ECE	3	0	0		3	3	50	50	100	3
4	РСС	21ECT504	Microwave Theory & Antennas	ECE	3	0	0		3	3	50	50	100	3
5	PCC	21ECL505	Communication Lab II	ECE	0	0	2		3	3	50	50	100	1
6	AEC	21RMT506	Research Methodology & Intellectual Property Rights	Any Department	2	0	0		2	2	50	50	100	2
7	HSSC	21CVT507	Environmental Studies	Civil/Chemistry	1	0	0			1	50	50	100	1
8	AEC	21ECL508x	Ability Enhancement Course- V	ECE						1/2	50	50	100	1
9	HSSC	21HSN509	Aptitude and Verbal ability skills		1	0	1	0		2	50		PP/NP	0
	l	I	1 	l					•	Total	450	400	800	18
				Ability Enhancen	nent Cours	e - V								
21ECL	.5081	Computer Cor	nmunication Networks Lab		21ECL50	83	Antenna Design & Testing							
21ECL	.5082	Communicatio	on Simulink Toolbox		21ECL50)8 4	Mi	crowave	es toolbox					

			Dr. Ambedkar I Outcome Based Education(OBE B.E. E Tentative Scheme of) and Choice Bas lectronics & Comm	ed Credi unication I lination eff	t Syste Enginee fective f	em (C ering	BCS) (As per N					
VI Se	emester													
Sl. No.	Course	Course Code	Course Title	Teaching		Teach	ning Hrs	/ Week				ination		Credits
	Category			Department	L	Т	Р	S	Total	Duration (Hrs)	CIE Marks	SEE Marks	Total Marks	
1	HSSC	21ECT601	Technological Innovation Management and Entrepreneurship								50	50	100	03
2	IPCC	21ECT602	Computer Organization & ARM Microcontrollers	ECE	2	2			4	3	50	50	100	04
3	PCC	21ECT603	VLSI Design & Testing	ECE	3				3	3	50	50	100	03
4	PEC	21ECT604X	Professional Elective -I	ECE	3				3	3	50	50	100	03
5	OEC	21ECT605X	Open Elective-I	ECE	3				3	3	50	50	100	03
6	PCC	21ECL606	VLSI Laboratory	ECE			2		2		50	50	100	01
7	MP	21ECM607	Mini Project	ECE			2		2		50	50	100	02
8	INT	21ECI608	Innovation/Entrepreneurship /Societal Internship								50	50	100	03
9	HSSC	21HSN609	Analytical & Reasoning skills	Placement Cells	2	0	0-		02		50		PP/NP	00
								Total			500	450	900	22

Research/Industrial Internship - At the End of the sixth / Seventh semester (in two cycles to accommodate all the students of the University) Research/Industrial Internship shall be carried out – Based on industrial/Govt./NGO/MSME/Rural Internship/Innovation/Entrepreneurship. All the students admitted shall have to undergo a mandatory internship of 24 weeks during the vacation of VI/VII semesters. A University Viva-Voce examination shall be conducted during VII/VIII semester and the prescribed credit shall be included in VII/VIII semester. The internship shall be considered as a head of passing and shall be considered for the award of degree. Those, who do not take up/complete the internship shall be declared fail and shall have to complete during subsequent University examination after satisfying the internship requirements. Research internship Students have to take up research internship is intended to give you the flavour of current research going on on a particular topic/s. The internships serve this purpose. They help students get familiarized with the field, the skill needed the effort amount and kind of effort required for carrying out research in that field.

Industry internships: This is an extended period of work experience undertaken by university/Institute students looking to supplement their degree with professional development. The students are allowed to prepare themselves for the workplace and develop practical skills as well as academic ones. It also helps them learn to overcome

unexpected obstacles and successfully navigate organizations, perspectives, and cultures. Dealing with "unexpected contingencies" helps students recognize, appreciate, and adapt to organization realities by tempering knowledge with practical constraints.

Mini-project work: Based on the ability/abilities of the student/s and recommendations of the mentor, a single discipline or a multidisciplinary Mini-project can be assigned to an individual student or a group having not more than 4 students. (or Mini Project is a laboratory-oriented course which will provide a platform to students to enhance their practical knowledge and skills by the development of small systems/applications) CIE procedure for

Mini-project: (i) Single discipline: The CIE marks shall be awarded by a committee consisting of the Head of the concerned Department and two senior faculty members of the Department, one of whom shall be the Guide. The CIE marks awarded for the Mini-project work, shall be based on the evaluation of project report, project presentation skill, and question and answer session in the ratio of 50:25:25. The marks awarded for the project report shall be the same for all the batch mates.

(ii) Interdisciplinary: Continuous Internal Evaluation shall be group-wise at the college level with the participation of all the guides of the college. The CIE marks awarded for the Mini-project, shall be based on the evaluation of project report, project presentation skill, and question and answer session in the ratio of 50:25:25. The marks awarded for the project report shall be the same for all the batch mates. SEE for Mini-project: (i) Single discipline: Contribution to the Mini-project and the performance of each group member shall be assessed individually in the semester-end examination (SEE) conducted at the department. (ii) Interdisciplinary: Contribution to the Mini-project and the performance of each group member shall be assessed individually in semester-end examination (SEE) conducted separately at the departments to which the student/s belongs **Open Elective Courses:** Students can select any one of the open electives offered by other Departments except those that are offered by the parent Department (Please refer to the list of open electives). Selection of an open elective shall not be allowed if, • The candidate has studied the same course during the previous semesters of the program. • The syllabus content of open electives is similar to that of the Departmental core courses or professional electives. • A similar course, under any category, is prescribed in the higher semesters of the program. • Registration to electives shall be documented under the guidance of the Programme Coordinator/ Advisor/Mentor

	Professional Elective Courses-I	Open Elective Courses-I				
Subject Code	Title	Subject Code	Title			
21ECE6041	Artificial Neural Networks (L:T:P :: 2:2:0)	21ECE6051	Communication Engineering (L:T:P :: 3:0:0)			
21ECE6042	Cryptography (L:T:P :: 2:2:0)	21ECE6052	Microcontrollers (L:T:P :: 3:0:0)			
21ECE6043	Python Programming (L:T:P :: 2:0:2)	21ECE6053	Basic VLSI Design (L:T:P :: 3:0:0)			
21ECE6044	Micro Electro Mechanical Systems (L:T:P :: 3:0:0)	21ECE6054	Electronic Circuits with Verilog (L:T:P :: 2:0:2)			
		21ECE6055	Sensors & Actuators (L:T:P :: 3:0:0)			

Assessment and Evaluation method

V Semester:

- **21ECT502- Microprocessor & Microcontrollers** shall have the 03 hours of theory examination (SEE), however, practical sessions question shall be included in the theory question papers
- ESC or ETC, of 03 credits Courses shall have only a theory component (L: T :P:S=3:0:0:0) or if the nature the of course required practical learning then the syllabus shall be designed as an Integrated course (L: T:P:S= 2:0:2:0). All PLC courses are Integrated courses.
- All 01 Credit courses shall have the SEE of 02 hours duration and the pattern of the question paper shall be MCQ
- Integrated courses (IPCC) will have 50 marks CIE and 50 Marks SEE.
- Non-integrated courses (PCC) have 50 marks CIE (including 5 marks Assignment and 5 marks Group Activity) and 50 Marks SEE.

VI Semester:

- **21ECT602- Computer Organization & ARM Microcontrollers** shall have the 03 hours of theory examination (SEE), however, practical sessions question shall be included in the theory question papers
- ESC or ETC, of 03 credits Courses shall have only a theory component (L: T :P:S=3:0:0:0) or if the nature the of course required practical learning then the syllabus shall be designed as an Integrated course (L: T:P:S= 2:0:2:0). All PLC courses are Integrated courses.
- All 01 Credit- courses shall have the SEE of 02 hours duration and the pattern of the question paper shall be MCQ
- Integrated courses (IPCC) will have 50 marks CIE and 50 Marks SEE.
- Non-integrated courses (PCC) have 50 marks CIE (including 5 marks Assignment and 5 marks Group Activity) and 50 Marks SEE.

DIGITAL COMMUNICATION								
Course Code:	21ECT501	CIE Marks:	50					
Teaching Hours/Week (L:T:P:S):	3:0:0:2	SEE Marks:	50					
Total Hours of Pedagogy:	40	Total Marks:	100					
Credits:	3	Exam Hours:	3					

Course objectives:

1. Understand the mathematical representation of signal, symbol, and noise.

2. Understand the concept of signal processing of digital data and signal conversion to symbols at the transmitter and receiver.

3. Compute performance metrics and parameters for symbol processing and recovery in ideal and corrupted channel conditions.

4. Compute performance parameters and mitigate channel induced impediments in corrupted channel conditions.

Module-1

Bandpass Signal to Equivalent Low pass:

Hilbert Transform, Pre-envelopes, Complex envelopes, Canonical representation of bandpass signals, Complex low pass representation of bandpass systems, Complex representation of band pass signals and systems (Text 1: 2.8, 2.9, 2.10, 2.11, 2.12, 2.13).

Line codes: Unipolar, Polar, Bipolar (AMI) and Manchester code and their power spectral densities (Text 1: Ch 6.10). Overview of HDB3, B3ZS, B6ZS (Ref.1: 7.2)

Teaching Learning Method:	Lectures, Interactive (Q & A discussion), Activity/Assignment based
RBT Level:	L1, L2, L3
	Module-2

Signaling over AWGN Channels-

Introduction, Geometric representation of signals, Gram-Schmidt Orthogonalization procedure, Conversion of the continuous AWGN channel into a vector channel, Optimum receivers using coherent detection: ML Decoding, Correlation receiver, matched filter receiver.

(Text 1:7.1, 7.2, 7.3, 7.4)

Teaching Learning Method:	Lectures, Interactive (Q&A discussion), Activity/Assignment based
RBT Level:	L1, L2, L3, L4
	Module-3

Digital Modulation Techniques:

Phase shift Keying techniques using coherent detection: generation, detection and error probabilities of BPSK and QPSK, M ary PSK, M-ary QAM. (Relevant topics in Text 1 of 7.6, 7.7).

Frequency shift keying techniques using Coherent detection: BFSK generation, detection and error probability (Relevant topics in Text 1of 7.8).

Non coherent orthogonal modulation techniques: BFSK, DPSK Symbol representation, Block diagrams treatment of Transmitter and Receiver, Probability of error (without derivation of probability of error equation) (Text 1: 7.11, 7.12. 7.13).

8 8	Lectures, Interactive (Q&A discussion), Activity/Assignment based
RBT Level:	L1, L2, L3, L4
	Module-4

Communication through Band Limited Channels:

Digital Transmission through Band limited channels: Digital PAM Transmission through Band limited Channels, Signal design for Band limited Channels: Design of band limited signals for zero ISI-The Nyquist Criterion (statement only), Design of band limited signals with controlled ISI-Partial Response signals, Probability of error for detection of Digital PAM: Probability of error for detection of Digital PAM with Zero ISI, Symbol-by-Symbol detection of data with controlled ISI (Text 2: 9.1, 9.2, 9.3.1, 9.3.2). Channel Equalization: Linear Equalizers (ZEE, MMSE). (Text 2: 9.4.2).

Chamber Equalization: Embar Equalizers (21 E, MINSE), (Text 2: 9:1.2).								
Teaching Learning Method:	Lectures, Interactive (Q&A discussion), Activity/Assignment based							
RBT Level:	L1, L2, L3, L4							
	Module-5							

Principles of Spread Spectrum:

Spread Spectrum Communication Systems: Model of a Spread Spectrum Digital Communication System, Direct Sequence Spread Spectrum Systems, Effect of De-spreading on a narrowband Interference, Probability of error (statement only), Some applications of DS Spread Spectrum Signals, Generation of PN Sequences, Frequency Hopped Spread Spectrum, CDMA based on IS-95 (Text 2: 11.3.1, 11.3.2, 11.3.3, 11.3.4, 11.3.5, 11.4.2).

Teaching Learning Method:	Lectures, Interactive (Q&A discussion), Activity/Assignment based
RBT Level:	L1,L2,L3

Course outcomes:

At the end of the course the student will be able to:

CO1. Understand the representation of bandpass signals into its' equivalent low pass signals and properties of various line code formats and their usage.

CO2. Analyse and compute the performance parameters of two different receiver architectures when lowpass and band pass symbol sets defined over symbol period are transmitted over noisy and noiseless bandlimited channel.

CO3. Generate and Evaluate different M-ary symbol sets on performance parameters at the receiver side under ideal and corrupted bandlimited channels.

CO4. Demonstrate the digital transmission of bandpass signals through bandlimited channels incorporating signal design processed at the receiver to meet specified performance criteria.

CO5. Understand the principles of spread spectrum communications to identify its application to recent communication systems in use today.

Suggested Learning Resources:

Text Books:

1: Simon Haykin, "Digital Communication Systems", John Wiley & sons, First Edition, 2014, ISBN 978-0-47 1-64735-5.

2: John G Proakis and Masoud Salehi, "Fundamentals of Communication Systems", 2014 Edition, Pearson Education, ISBN 978-8—131-70573-5.

3: B.P.Lathi and Zhi Ding, "Modern Digital and Analog communication Systems", Oxford University Press, 4th Edition, 2010, ISBN: 978-0-198-07380-2.

Reference Books

1: Ian A Glover and Peter M Grant, "Digital Communications", Pearson Education, Third Edition, 2010, ISBN 978-0-273-71830-7.

2: Bernard Sklar and Ray, "Digital Communications - Fundamentals and Applications", Pearson Education, Third Edition, 2014, ISBN: 978-81-317-2092-9.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning Activity 1: Presentation on various topics Activity 2: Small projects on applications of digital communication Activity 3: Group discussion on various topics of digital communication

							CO-P	O Ma	pping						
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	3	2	1			1	1	2		1		2	2	2	2
CO2	3	3	2	2		2	1	2		2		3	3	3	3
CO3	3	3	2	2		2	2	2		3		3	3	3	3
CO4	3	3	2	2		2	2	2		3		3	3	3	3
CO5	2	1	1	1		2	2	2		3		3	2	2	3
High-3	B, Medi	um-2,	Low-1												

MICRO	PROCESSOR & MICR	OCONTROLLER						
Course Code:	21ECT502	CIE Marks:	50					
Teaching Hours/Week (L:T:P:S)		SEE Marks:	50					
Total Hours of Pedagogy:	52	Total Marks:	100					
Credits:	04	Exam Hours:	03					
Course objectives:		l						
i. To illustrate the architecture o	f 8051 Micro controller.							
ii. To understand the Special Fun	nction Registers, addressin	ng modes and memory orgar	nization.					
iii. To introduce Assembly langua	age programming of 8051	Micro controller.						
iv. To understand the RISC V mid	croprocessors and Instruct	tion Set Architecture.						
Introduction to microprocessors	Module-1		08 hrs					
8051 Microcontroller: The 8051 Memory interfacing. Classificatio addressing, Direct addressing, Inc. addressing. (TEXT 1 and TEXT 2	on of Instruction, Address direct addressing, relative	sing modes: Immediate add	lressing, Register					
Teaching Learning Method:	Chalk and Talk, PowerP	oint Presentation, YouTube	videos					
RBT Level: L1, L2, 13								
RBT Level:	L1, L2, 13		0					
	Module-2	inne Dete twonefor instan	07 hrs					
RBT Level: 8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations.	Module-2 amming: 8051 instructions, s, Branch instructions,	Subroutine instructions,	actions,Arithmetic Bit manipulation					
8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming:	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As	Subroutine instructions, issembly language programs	actions,Arithmetic Bit manipulation and Time delay					
8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations.	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As	Subroutine instructions, issembly language programs	actions,Arithmetic Bit manipulation and Time delay					
8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations. Introduction to Embedded C: C	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As data types, logical operation	Subroutine instructions, issembly language programs	actions,Arithmetic Bit manipulation and Time delay ng embedded C					
8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations. Introduction to Embedded C: C (TEXT 2 and TEXT 3)	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As data types, logical operation	Subroutine instructions, seembly language programs	actions,Arithmetic Bit manipulation and Time delay ng embedded C					
8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations. Introduction to Embedded C: C (TEXT 2 and TEXT 3) Teaching Learning Method: RBT Level:	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As data types, logical operation Chalk and Talk, PowerP L1, L2, L3 Module-3	Subroutine instructions, ssembly language programs ions, programming 8051 usi oint Presentation, YouTube	actions,Arithmetic Bit manipulation and Time delay ng embedded C videos 09 hrs					
 8051 Instructions and Progra instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations. Introduction to Embedded C: C (TEXT 2 and TEXT 3) Teaching Learning Method: RBT Level: Timers/counters: 8051 timers/co delay and counting operation using Communication, 8051 Serial Communication, 8051 Serial Communication: Serial Communication: Data co Communication, Programming in 8051 interrupts and interfacing: Basics of I/O concepts, I/O Port O Teaching Learning Method: 	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As data types, logical operation Chalk and Talk, PowerP L1, L2, L3 Module-3 unters, delay program, co g assembly and C languag munication, Programming ommunication, Basics of assembly and C. Interrupts and Basics of i peration, Interfacing 8051 Chalk and Talk, PowerP	Subroutine instructions, ssembly language programs ions, programming 8051 usi ounter programming 8051 t ge. Data communication, Bas g in assembly and C. f Serial Data Communication	actions, Arithmetic Bit manipulation Bit manipulation and Time delay ng embedded C videos 09 hrs imers to generate sics of Serial Data tion, 8051 Serial and Applications: Γ 3)					
 8051 Instructions and Progrations instructions, Logical instructions instructions. 8051 programming: calculations. Stack operations. Introduction to Embedded C: C (TEXT 2 and TEXT 3) Teaching Learning Method: RBT Level: Timers/counters: 8051 timers/condelay and counting operation using Communication, 8051 Serial Communication: Data construction, Programming in 8051 interrupts and interfacing: Basics of I/O concepts, I/O Port O 	Module-2 amming: 8051 instructions, s, Branch instructions, Assembler directives, As data types, logical operation Chalk and Talk, PowerP L1, L2, L3 Module-3 unters, delay program, co g assembly and C languag munication, Programming ommunication, Basics of assembly and C. Interrupts and Basics of i peration, Interfacing 8051	Subroutine instructions, ssembly language programs ions, programming 8051 usi coint Presentation, YouTube ounter programming 8051 t ge. Data communication, Bas g in assembly and C. f Serial Data Communicat nterrupts, 8051 Interfacing to DAC,LED/LCD. (TEX)	actions, Arithmetic Bit manipulation Bit manipulation and Time delay ng embedded C videos 09 hrs imers to generate sics of Serial Data tion, 8051 Serial and Applications: Γ 3)					

RISC-V Microprocessors: Introduction, Modular vs. Incremental ISAs, ISA Design 101

RV32I: RISC-V Base Integer ISA: Introduction, RV32I Instruction formats, RV32I Registers, RV32I Integer Computation, RV32I Loads and Stores, RV32I Conditional Branch, RV32I Unconditional Jump, RV32I Miscellaneous, Comparing RV32I, ARM-32, MIPS-32, and x86-32 using Insertion Sort.

RISC-V Assembly Language: Introduction, Calling convention, Assembly, Linker, Static vs. Dynamic Linking, Loader.

Teaching Learning Method:	Chalk and Talk, Power point presentations, Programming assignments					
RBT Level:	L1, L2, L3					
	08 hrs					

RV32M: Multiply and Divide- Introduction

RV32F and RV32D: Single- and Double-Precision Floating Point- Introduction, Floating-Point Registers, Floating-Point Loads, Stores, and Arithmetic, Floating-Point Converts and Moves, Miscellaneous Floating-Point Instructions, Comparing RV32FD, ARM-32, MIPS-32, and x86-32 using DAXPY.

RV32C: Compressed Instructions- Introduction, RV32A: Atomic Instructions- Introduction, RV32V: Vector- Introduction

Teaching Learning Method:	Chalk and Talk, Power point presentations, Programming assignments
RBT Level:	L1, L2, L3

PRACTICAL COMPONENT OF IPCC

Conduct the following experiments by writing Assembly Language Program (ALP) using ARM Cortex M3 Registers using an evaluation board/simulator and the required software tool

Sl. No.	Experiments	12 hrs
1	Data transfer programs-	
	i] WALP to transfer data between internal and external memories	
	ii] WALP to exchange data between internal and external memories	
2	Arithmetic operation programs-	
	i] WALP to add 10 bytes of data	
	ii] WALP to add multi bytes of data	
	iii] WALP to find the square and cube of an 8 bit binary number	
3	Logical operation programs-	
	i] Let X, Y, Z refer to the contents of the memory location 30h,31h,and 32h re	espectively, write
	an ALP to perform the following logical operations;	
	If X=00 perform the operation Y OR Z.	
	If X=01 perform the operation Y AND Z.	
	If X=02 perform the operation Y XOR Z.	
	ii] WALP to compare the bytes of data present at the memory location 21h and 2	22h and represent
	the result of comparison through the bits whose addresses are 00h and 01h.	
	If (21h)<(22h)then clear the bit at 01h and also set the bit at 00h.	
	If (21h)>(22h)then set the bit at 01h and also clear the bit at 00h.	
	If (21h)=(22h)then set the bit at 01h and also set the bit at 00h.	
	iii] WALP to stimulate the Boolean expression Eg: Y=A+BC.	

4	i] Parity Program- WALP to count the number of 1's in a byte which is be accepted from the
-	port 0 and displays the result on the port1.
	ii] Palindrome Program- WALP to check whether the gives byte is a valid bit palindrome, accept
	byte from the port0 and display ash if valid else 00H in port1.
5	Timer program-
U	WALP to generate the output value AAH and 55H alternatively at the Port 0 for every 2 sec.
6	Counter program-
Ũ	WALP to count the number of inputs to the counter_0 by configuring the timer as a
	counter in mode_1 and display the count in ports.
7	Design and implementation of RISC V Processor Subsystem using Verilog:
	a) Floating Point Addition & Subtraction.
	b) Floating Point Multiplication.
	c) Operand Logic.
	Demonstration Experiments (For CIE only not for SEE)
Conduct	the following experiments on an 8051 MC using evaluation version of Embedded 'C' & Keil
µvision-2	3 tool/compiler.
08	Demonstrate the serial communication- WALP to transfer the characters serially.
09	Demonstrate the interfacing of DAC programs-WALP to generate the wave forms
	i] Square wave
	ii] Triangle wave
	iii] Ramp wave (Both positive and negative)
10	Demonstrate the interfacing of LED programs-
	WALP to display the count (UP/DOWN/LED BLINKING)
	outcomes:
	nd of the course the student will be able to:
	derstand the features and architecture of 8051 Microcontroller.
-	ogram 8051 microcontroller using assembly language and embedded C.
	nfigure timers/counters of 8051 and understand serial communication and interrupts of 8051.
	derstand need of RISC V microprocessors and basics of RV32I.
	derstand basics of RV32M, RV32F, RV32D, RV32C, RV32A, RV32V.
66	ed Learning Resources:
Text Bo	
	heng Liu, Glenn A.Gibson, "Microcomputer Systems: The 8086/8088 Family Architecture,
e	ming, and Design"
	eth J. Ayala, "The 8051 Microcontroller Architecture, Programming & Applications", 2e Penram onal, 1996 / Thomson Learning 2005.
	ammad Ali Mazidi, Janice Gillespie Mazidi and Rollin D. McKinlay, "The 8051
	ntroller and Embedded Systems – using assembly and C", PHI, 2006 / Pearson, 2006.
	RISC-V Reader: An Open Architecture Atlas Beta Edition, 0.0.1, David Patterson and Andrew
	an, October 4, 2017
<u>w</u> aterina	
	Based Learning (Suggested Activities in Class)/ Practical Based learning

							CO-P	°O Map	ping						
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3					2	2	2				2	1	3	1
CO2	3	3	3			2		2	1			2	1	3	1
CO3	3	3	3		3	2		2	1			2	1	3	1
CO4	3	2	3		3	2		2	1			2	1	3	1
CO5	3	2	2		2	2		2	1				1	3	1
High-3	, Mediu	ım-2, L	.ow-1												

COM	PUTER COMMUNICAT	ION NETWORKS							
Course Code:	21ECT503	CIE Marks:	50						
Teaching Hours/Week (L:T:P:S		SEE Marks:	50						
Total Hours of Pedagogy:	40	Total Marks:	100						
Credits:	3	Exam Hours:	03						
Course objectives:	5	Exam nours.	03						
This course will enable students	<u>.</u>								
		noo and TCD/ID model							
1. Provide Insight into the basics	0		limlr lorron						
2. Study of access links, protocol	-	-	link layer.						
3. Understanding of routing algor		les of the network layer.							
4. Understand Protocol technique	1 1								
5. Identify Services, Protocols, d		ty of the application layer	001						
	Module-1		08 hrs						
Introduction: Data communicat	•								
Network Models: TCP/IP Protoc		Connecting devices.							
(1.1, 1.2, 1.3.1-1.3.4, 2.2, 2.3, 17	1.1-17.1.3 of Text)								
Teaching Learning Method:	Chalk and talk method.	PowerPoint Presentation,	YouTube videos,						
Animation of OSI and TCP-IP protocol suites, Example of ARP ar									
	RARP.	1	1						
RBT Level:	L1, L2, L3								
	Module-2		08 hrs						
Data-Link Layer: Introduction,			00 1115						
Error Detection and Correction		lundancy Check Checksum							
Media Access Control: Random		•							
Wired LANs: Ethernet Protocol,		s, Chalinenzation, Virtual LF	11N.						
(9.1, 9.2.1, 9.2.2, 10.1, 10.3.1, 10		2 12 1 12 2 1 12 2 2 17 1	$17.2 \text{ of } T_{\text{ovt}}$						
`									
Teaching Learning Method:		PowerPoint Presentation,							
	Animations showing Fra	ming, CSMA, Connecting	devices Problems						
	on ALOHA, CSMA, Fran								
		ning and Standard Ethernet.							
RBT Level:	L1, L2, L3	ning and Standard Ethernet.							
KBT Level:	L1, L2, L3 Module-3	ning and Standard Ethernet.	08 hrs						
RBT Level: Network Layer: Network Lay	Module-3		08 hrs						
	Module-3		08 hrs						
Network Layer: Network Lay Protocol.	Module-3 er services, Packet Switc		08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter	Module-3 er services, Packet Switc net Protocol (IP).		08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor	Module-3 er services, Packet Switc net Protocol (IP). ithms.		08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text)	hing, IPV4 Addresses, IPv	08 hrs 76 addressing and						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method,	hing, IPV4 Addresses, IPv PowerPoint Presentation,	08 hrs 6 addressing and YouTube videos,						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method:	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout	hing, IPV4 Addresses, IPv	08 hrs 6 addressing and YouTube videos,						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3	hing, IPV4 Addresses, IPv PowerPoint Presentation,	08 hrs 76 addressing and YouTube videos, n Addressing,						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level:	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4	hing, IPV4 Addresses, IPv PowerPoint Presentation,	08 hrs 6 addressing and YouTube videos,						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction,	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Fransport Layer Protocols.	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of	08 hrs 76 addressing and 76 youTube videos, n Addressing, 08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction, Transport-Layer Protocols in	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Fransport Layer Protocols.	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of	08 hrs 76 addressing and 76 youTube videos, n Addressing, 08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction,	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Fransport Layer Protocols.	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of	08 hrs 76 addressing and 76 youTube videos, n Addressing, 08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction, Transport-Layer Protocols in	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Transport Layer Protocols. the Internet: Port num	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of	08 hrs 76 addressing and YouTube videos, n Addressing, 08 hrs						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction, Transport-Layer Protocols in Control Protocol. 23.1, 23.2, 24.1.2 - 24.3.5 of Text	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Fransport Layer Protocols. the Internet: Port num	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of bers, User Datagram Proto	08 hrs 76 addressing and 76 addressing and YouTube videos, an Addressing, 08 hrs col, Transmission						
Network Layer: Network Lay Protocol. Network Layer Protocols: Inter Unicast Routing: Routing Algor (18.1, 18.2, 18.4, 19.1, 20.1, 20.2) Teaching Learning Method: RBT Level: Transport Layer: Introduction, Transport-Layer Protocols in Control Protocol.	Module-3 er services, Packet Switc net Protocol (IP). ithms. ,22.1 ,22.2 of Text) Chalk and talk method, Animation of DHCP, rout L1, L2, L3 Module-4 Transport Layer Protocols. the Internet: Port num	hing, IPV4 Addresses, IPv PowerPoint Presentation, ing protocols, Numericals of	08 hrs 76 addressing and 76 addressing and YouTube videos, a Addressing, 08 hrs 08 hrs 08 hrs col, Transmission YouTube videos, and the state of t						

RBT Level:	simulators. L1, L2, L3	
	Module-5	08 hrs

Application Layer: Introduction, **Standard Client – Server Protocols**: World Wide Web and HTTP, Domain Name system: Name space, DNS in internet, Resolution, DNS Messages, Registrars, DDNS, security of DNS, Network Security.

(25.1, 26.1.2, 26.2, 26.3, 26.6, 31.1 of Text)

Teaching Learning Method:	Chalk and talk method, PowerPoint Presentation, YouTube videos,
	Animation/Implementation of HTTP, FTP, DNS using network
	simulators.
RBT Level:	L1, L2, L3

Course outcomes:

At the end of the course the student will be able to:

CO1. Define the network components, layers, addressing, topology, and connectivity and network types for data transmission.

CO2. Distinguish the basic network configurations and standards associated with each network.

CO3. Describe the layering architecture of computer networks and distinguish between the OSI reference model and TCP/IP protocol suite.

CO4. Identify the protocols and functions associated with the transport layer services.

CO5.Construct a network model and determine the routing of packets using different routing algorithms and identify the concepts of Network security.

Suggested Learning Resources:

Text Books:

1: Forouzan, "Data Communications and Networking", 5th Edition, McGraw Hill, 2013, ISBN: 1-25-906475-3.

Reference Books

1: James J Kurose, Keith W Ross, "Computer Networks", Pearson Education.

2: Wayne Tomasi, "Introduction to Data Communication and Networking", Pearson India, 1st edition.

3: Andrew Tannenbaum, "Computer Networks", Prentice Hall.

4: William Stallings, "Data and Computer Communications", Prentice Hall

Web Links:

https://nptel.ac.in/courses/106105183.

TCP/IP Tutorial and Technical Overview, (IBM Redbook) - Download From http://www.redbooks.ibm.com/abstracts/gg243376.html

TCP/IP Guide, Charles M Kozierok, Available Online - http://www.tcpipguide.com/ Request for Comments (RFC) - IETF - http://www.ietf.org/rfc.html

https://cosmolearning.org/courses/computer-networks-524/video-lectures/

<u>https://www.eecis.udel.edu/~bohacek/videoLectures/ComputerNetworking/ComputerNetworking_v2.html</u> Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Activity 1: Implementation of simple networks and various networking protocols and algorithms using simulators like NCTUns / CISCO packet tracer and measurement of various parameters using WireShark Activity 2: Implementation of simple networks and various networking protocols and algorithms in

C/C++/Python

CO-PO Mapping

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	-	3	3	3	-	-	-	-	3	3	-	-	-	-	-
CO2	-	3	3	3	3	-	-	-	3	3	-	-	1	-	-
CO3	-	3	3	3	3	-	-	-	3	3	-	3	-	1	-
CO4	-	3	3	3	3	-	-	-	3	3	-	3	2	-	-
CO5	-	3	3	3	3	-	-	-	3	3	-	3	2	2	-

High-3, Medium-2, Low-1

MI	ICROWAVE THEORY A	ND ANTENNA	
Course Code:	21ECT504	CIE Marks:	50
Teaching Hours/Week (L:T:P:S	S): 3:0:0:0	SEE Marks:	50
Total Hours of Pedagogy:	40	Total Marks:	100
Credits:	03	Exam Hours:	03 Hrs
Course objectives:			
1. Understanding the basics of m	icrowave and waveguides.		
2. Understanding the concepts of	microwave networks, mic	rowave passive devices and	semiconductor
devices.			
3. Understanding microwave tube	es, microwave design prin	ciples and antenna basics.	
4. Understanding the importance	of point sources, arrays ar	d radiations from wires.	
5. To understand different types of	of antennas like aperture, r	eflector, broadband and Mic	rostrip antennas.
	Module-1		08 hrs
Introduction to Microwaves -	History of Microwaves. N	Microwave Frequency band	s, applications of
Microwaves, Losses associated v	•		
transmission.		,FFF	
Waveguides-Rectangular waveg	uide Introduction to Circu	lar waveguide (No derivatio	ons and Numerical
examples), Strip line, Micro strip			
1 // 1 /	Chalk and Talk, YouTube	videos	
8 8	L1, L2	lucos	
	Module-2		08 hrs
Microwave Network Analysis		r microwaya circuita Scatt	
•	-		-
Microwave Passive devices and s		-	
Coupler, Power Divider, Magic		ave Semiconductor Devices	s - Gunn Diodes,
IMPATT diodes, PIN diodes. TE	· · · · · · · · · · · · · · · · · · ·	1.0	
0 0	Lecture-based learning and	Group learning	
RBT Level:	L1, L2		001
	Module-3	N A A A A A	08 hrs
Microwave Tubes: Klystron- tw		•	•
Antenna Basics - Physical conc	1	•	-
radiation patterns, beam area, rad	•		-
apertures, effective height, bandy	width, radiation efficiency	, radio communication Link	and antenna field
zones. TEXT 1,2,3.4			
Teaching Learning Method:	Lecture-based learning and	l Group learning	
RBT Level:	L1, L2		
	Module-4		08 hrs
Radiations from wires: Short ele	ectric dipole, resistance of o	lipole, Half wave dipole ante	nna, folded dipole
antennas.			
Point Sources & their arrays -	Arrays, Point source, Pov	wer theorem and its applica	tion, Examples of
power patterns, Field patterns,	•		-
isotropic sources, principle of pa			
spacing, broad side, end fire array		2	

spacing, broad side, end fire arrays. TEXT 3,4

Teaching Learning	g Meth	iod:	Lect	ure-ba	sed lea	arning	and G	roup le	arning				
RBT Level:				L2, L3		U		1	C				
				Mod	lule-5							08	hrs
Aperture and Ref	lector .	Anter	nnas-	Huyge	ens' pri	inciple	, Babi	net's pi	rinciple	, Radiat	tion fro	m secto	oral and
pyramidal horns: de	esign c	oncep	ots, pri	ime-fo	cus pa	raboli	c refle	ctor an	d casse	grain ar	tennas		
Broadband Anten	nas- L	og-pe	riodic	and Y	agi-U	da ante	ennas,	freque	ncy ind	epender	nt anter	nnas, br	oadcast
antennas. Micro str	ip Ante	ennas	- Basio	c chara	acterist	tics of	micro	strip a	ntennas	, feedin	g meth	ods. TE	XT 3,4
Teaching Learning	g Meth	nod:	Lect	ure-ba	sed lea	arning	and G	roup le	arning				
RBT Level:			L1, I	L2, L4									
Course outcomes:			•										
At the end of the c	ourse	the st	tuden	t will	be abl	e to:							
CO1. Identify the n	nicrow	ave fi	requen	icy bai	nd, its	applica	ations	and dif	ferent t	ypes of	waveg	uides	
CO2. Analyse micr	owave	netw	orks, i	microv	wave p	assive	devic	es and	semico	nductor	device	s.	
CO3. Apply microv	vave d	esign	princi	iple, m	nicrow	ave tuł	bes and	d anten	na basi	cs.			
CO4. Be able to ana	alyse th	ne rad	iation	patter	ns fror	n diffe	rent ty	pes of	wires, p	point so	urces a	nd their	arrays.
CO5. Illustrate and	design	n ante	nnas li	ike apo	erture,	reflect	tor, an	d broad	lband. I	Microst	rip ante	enna.	
Suggested Learnin	ng Res	ource	es:										
 J.D. Kraus, Ante C.A. Balanis, An Reference Books Microwave Devi M.Kulkarni., "M R.E. Collin, Ante I.J. Bahl and P. E 	tenna ' ces and icrowa	Theor d circ ive de ind Ra	ry - Aı uits- L evices adio W	Liao / I and R Vave P	s and I Pearson adar E Propaga	Design, n Educ ngg."U ation, 1	, John cation. Jmesh McGra	Wiley, 1992 Public w Hill	1982. eations, , 1985.				
Web Links: 1. www.nptel.in 2. https://www.acad 3. https://www.acad Design_Joel_R_Ha 4. www.youtube/m Activity Based Lea 1: Creating physica 2: Exploring new te	demia. llas_2(icrowa arning l modu	edu/1 009 <u>ive , v</u> 5 (Sug ules	37594 <u>vww.y</u> gesteo	43/Ba <u>youtub</u> d Activ resenti	sic_Aı <u>e/anter</u> vities i	ntennas nnas in Clas	s_Und ss)/ Pr	erstanc	ling_Pr	actical_	Antenr		
		D O (1	D 07		CO-P				DOIL	DO 10	D0 24	Daga	Deca
P01 P02 C01 3 1	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2 2	PSO3
5 1	2											2	
	3	2			1					1	2	2	
CO4 3 3	2	2			1					1	2	2	

CO5	3	3	2	2		1			1	2	2	
High-3	8, Medi	um-2,	Low-1									

COMMUNICATION LAB II											
Course Code	21ECL505	CIE Marks	50								
Teaching Hours/Week (L: T: P: S)	0:0:2:0	SEE Marks	50								
Credits	01	Exam Hours	03								
Course objectives:											
This laboratory course enables studen	its to										
• Design and demonstrate commu		•	tion techniques.								
 To simulate Source coding Algo To simulate Error correcting and 	Ũ		ada								
 To simulate Error correcting and Simulate the networking conception 	•	-									
Understand entropies and mutua	=	-									
Sl.No. Experi	ments										
Implement the following	g using discrete co	mponents									
1 FSK generation and detection	n										
2 PSK generation and detection	n										
3 DPSK Transmitter and recei	ver										
4 QPSK Transmitter and Rece	iver										
Implement the following in C/C-	++/MATLAB/Scila	b/Python or any other S	Suitable software								
5 Write a program to encode b											
6 Write a program to encode b											
7 Write a program to encode l											
and decode it.	,	((-, , , , ,	,								
8 For a given data, use CRC- program for the		to obtain the CRC code	. Verify the								
cases a) Without error b	,										
•	8 8	C/C++/MATLAB/Netw	ork simulator								
9 Write a program for congest	-		ansmission								
10 1 0		-									
11 Write a program for flow co		*									
12 Configure a simple network		0									
Configure a simple network			ware.								
	stration Experime										
13Configure and simulate simp14Simulate the BER perform			ada with gaparator								
sequences $g(1) = (1 \ 0 \ 1 \ 1)$ a scheme. Channel decoding	nd g(2) =(1 1 1 1)	on AWGN channel. Use	e QPSK modulation								
rate versus SNR (dB), i.e. Pe,b versus Eb/N0. Consider gain.	• •										
15 Simulate the BER performa modulation	nce of $(7, 4)$ Hamn	ning code on AWGN cha	nnel. Use QPSK								
scheme. Channel decoding	is to be performed	through maximum-likelil	hood decoding. Plot								
the bit error rate versus SN	R (dB), i.e. Pe,b ve	rsus Eb/N0. Consider bin	nary input vector of								
size 5 lakh bits. Use the fol	lowing parity chec	k matrix for the (7, 4) H	amming code. Also								

	find the coding gain.
	$\begin{array}{cccccccccccccccccccccccccccccccccccc$
	0 0 1 1 1 0 1 Simulate the BER performance of rate 1/3 Turbo code. Turbo encoder uses tw
10	
	systematic encoders with $G(D) = \begin{bmatrix} 1+D & 4\\ 1+D+D^2+D^3+D^4 \end{bmatrix}$ and pseudo-random interleaver. Use QPSE
	systematic encoders with $G(D) = [1, D+D^2+D^3+D^4]$ and pseudo-random interfeaver. Use QPSF
	modulation scheme. Channel decoding is to be performed through maximum a-posterior
	(MAP) decoding algorithm. Plot the bit error rate versus SNR (dB), i.e. Pe,b versus Eb/N(
	Consider binary input vector of size of around 3 lakh bits and the block length as 1038
	bits. Also find the coding
	gain.
Cor	rse outcomes (Course Skill Set):
On	he completion of this laboratory course, the students will be able to:
1.	Design and test the digital modulation circuits and display the waveforms.
2.	To Implement the source coding algorithm using $C/C++/MATLAB$ code.
3.	To Implement the Error Control coding algorithms using C/C++/ MATLAB code.
4.	Illustrate the operations of networking concepts and protocols using C programming and netwo
1.	simulators.
Sug	gested Learning Resources:
U	Simon Haykin, "Digital Communication Systems", John Wiley & sons, First Edition, 2014,
	ISBN 978-0-471-64735-5.
	K Sam Shanmugam, "Digital and analog communication systems", John Wiley India Pvt. Ltd,
2.	1996.

	CO-PO Mapping														
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	3	3	2					1	1	1		1	3	3	
CO2	3	3	2					1	1	1		1	3	3	
CO3	3	3	2					1	1	1		1	3	3	
CO4	CO4 3 3 2 1 1 1 1 3 3														
` Hig	High-3, Medium-2, Low-1														

	COMPUTE	R COMMUNICATION NET	WORKS LAB										
Coi	ırse Code:	21ECL5081	CIE Marks:	50									
	ching Hours/Week (L:T:P:S):	0:0:1:0(L - T – P)	SEE Marks:	50									
	al Hours of Pedagogy:	12	Total Marks:	100									
	edits:	1	Exam Hours:	03									
Cou	ırse objectives:												
	s course will enable students to:												
	Demonstrate the simulation of few		•										
	Demonstrate the network commun												
	Demonstrate the detection and cor Simulate the configuration and ver												
4. 5	simulate the configuration and ver	Syllabus Contents	•										
1	Write a C program to implement	V											
-	Write a C program to implement Bit Stuffing and DeStuffing. RBT Level: L2, L3												
2	Write a C program to simulate a Character Stuffing and Destuffing for a given message.												
	RBT Level: L2, L3												
3	Write a C program to compute a	Polynomial Checksum for a gi	ven binary data fran	ne.									
	RBT Level: L2, L3												
4		Shortest Path Algorithm											
	Write a C program to simulate a Shortest Path Algorithm.												
5	RBT Level: L2, L3 Using TCP/IP Sockets, write a client server program to make client to communicate with Server using												
5	Using TCP/IP Sockets, write a client-server program to make client to communicate with Server using socket programming techniques in python.												
	RBT Level: L2, L3												
6	Using TCP/IP Sockets, write to	program to develop server and	client file sharing sy	stem using Socket									
U	Programming in python.	program to develop server and	enent me sharing sy	stem using socket									
	RBT Level: L2, L3												
	RD1 ECVCI. E2, E5	Part B											
7	Configuring and Verifying LA		umber of HOSTS, c	reate a network by									
,	connecting Networking Devices	_											
	Configuration includes HOS			E. TELNET and									
	ENABLE), MANAGEMENT I			, iteliter and									
	RBT Level: L2, L3												
8	Configuring and Verifying VL	AN: Create a network for a giv	en number of HOS	TS and Establish a									
	communication between the ho	_											
	Configuration includes Switch p		-	, only the sume.									
	RBT Level: L2, L3	on comparation and encapsuid	monious.										
9	Configuring and Verifying IP	Routing Using IP routing Fo	tablish a communic	ation between the									
	hosts by connecting the Netwo												
	networks.	Jik Devices, configure them a	ind verify the same	among amerent									
	Configuration includes:												
	1. Static Routing												
	e	F/FICDD)											
	2. Dynamic Routing (RIP/OSP)	() LIUKE)											
	RBT Level: L2, L3												

10															
	dynamically to the hosts and verify the same. a. For One Broadcast Domain														
	a. For C	One Br	oadcas	st Don	nain										
	b. For M	/any]	Broadc	ast Do	omain										
	RBT L	evel:]	L 2, L3												
11	Config	ure a	mail se	erver:	Confi	gure n	nail ser	ver us	ing Pa	cket tra	acer.				
	RBT L														
12	Demon	stratio	n of Se	erial C	ommu	nicatio	on usir	ıg							
	(i) RS2	32													
	(ii) MO	DEM	COM	MUNI	CATIO	DN									
	(iii) FIBER OPTIC COMMUNICATION														
	RBT Level: L2														
	PART-C														
13	[Simula	tion (Case-St	udy] I	Dr. AI	[is gra	anted a	a block	c of ad	dresses	s startin	g from	192.16	8.100.0	/24. The
	Dr. AIT	Colle	ege co	mmitte	ee dec	ided to	o distri	ibute t	hese b	locks o	of addr	esses to) THRE	E Dep	artments
	Dr. AIT College committee decided to distribute these blocks of addresses to THREE Departments with each department receiving just FOUR Addresses.														
	1. Design the sub blocks and give the slash notation to each sub block														
14															
	Constraints:														
	a. Estab	olish a	comm	unicat	ion wi	thin th	e Dep	artmer	nts.						
	b. Only	HOD	's of e	ach D	epartm	ent ca	in com	munic	ate (Si	ingle u	ser fror	n each	Departr	nent) w	ith each
	other.														
15	Configu	ire poi	rt secu	rity on	the in	terface	e of the	e switc	h for t	the netw	work to	pology.			
Cou	irse outo	comes	:												
Att	the end o	of the	course	e the s	tuden	t will l	be able	e to:							
CO	1.Condu	ct an e	experin	nent to	simul	ate va	rious p	rotocc	ols of c	lata lin	k and n	etwork	layer.		
CO	2.Config	ure an	d verif	y VLA	AN and	l swite	ches.								
CO	3.Write t	he pro	gram t	o veri	fy the	detecti	ion and	1 corre	ction of	of error					
CO	4.Demor	strate	the da	ta com	nmunic	ation	betwee	en two	syster	ns usin	g the c	ommun	ication	kit.	
CO	5.Write t	he pro	gram t	trans	sfer fil	e and	establi	sh con	nectio	n betw	een two	o device	es.		
							CO-P	PO Ma	pping	5					
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO	01 -	2	-	3	3	-	-	-	3	3	-	3	2	3	-
CO CO		2 2	-	3	3	-	-	-	3	3	-	3	2 2	3	-
CO	94 -	2	-	3	3	-	-	-	3	3	-	3	2	3	-
CO		2	-	3	3	-	-	-	3	3	-	3	2	3	-
Hig	h-3, Mediu	ım-2, I	70 M-1												

COMM	IUNICATION SIMULINK TOO	LBOX							
Course Code: 21ECL5082 CIE Marks: 50									
Teaching Hours/Week (L:T:P:S):	0:0:2:0	SEE Marks:	50						
Total Hours of Pedagogy:	13	Total Marks:	100						
Credits:	01	Exam Hours:	03						

Course objectives:

• To impart knowledge of simulation software in digital communications

• To develop skills required to build and analyze the performance of various simulated communication systems under different conditions

Sl. No	Experiments
1	Modulation & demodulation of a random binary data stream using 16 – QAM.
2	Bit error rate (BER) improvement using Pulse Shaping on 16 – QAM signal. (Use forward error
	correction (FEC) coding.)
3	Perform OFDM modulation and obtain time domain and frequency domain plots to show a low
	rate signal, a high-rate signal, and a frequency selective multipath channel response.
4	(a) Simulate basic OFDM with no cyclic prefix.
	(b) Perform Equalization, Convolution, and Cyclic Prefix Addition on basic OFDM.
5	OFDM with FFT Based Oversampling - Modify an OFDM+ Cyclic Prefix signal to efficiently
	output an oversampled waveform from the OFDM modulator.
6	Simulate a basic communication system in which the signal is first QPSK modulated and the
	subjected to Orthogonal Frequency Division Multiplexing (OFDM).
7	Obtain the scatter plots & eye diagrams of a QPSK signal to visualize the signal behaviour in
	presence of AWGN.
8	(a) Generate a multiband signal using the Communications Toolbox.
	(b) Random noise generation using Simulink & display histogram plots of Gaussian
	Rayleigh, Rician, and Uniform noise.
9	QPSK Transmitter and Receiver in Simulink.
10	Multipath Fading Channel in Simulink – For example: Simulate QPSK transmission over a
	• multipath Rayleigh fading channel and
	• a multipath Rician fading channel.
11	Adjacent and Co-Channel Interference using Simulink.
	• Use PSK-modulated signals to show the effects of adjacent and co-channel interference
	on a transmitted signal.
12	Modulation Classification with Deep Learning
	• Predict Modulation Type Using CNN

At the end of the course the student will be able to:

1. Perform sampling, aliasing, filtering, and quadrature modulation through simulation.

2. Plot signal space representation of digital modulation techniques.

3. Design and implement a pulse shape and matched filter to avoid inter-symbol interference and maximize receiver SNR.

4. Demonstrate advanced wireless communication techniques like Multipath fading, CCI etc. and model the same using MATLAB / Simulink

							CO-I	PO Ma	apping	5					
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO
CO1															
CO2															
CO3															
CO4															

	ANT	ENNA DESIGN & T	ESTING								
Course Code:		21ECL5083	CIE Marks:	50							
Teaching Hours	/Week (L:T:P:S):	0:0:2:0	SEE Marks:	50							
Total Hours of I	Pedagogy:	13	Total Marks:	100							
Credits:		01	Exam Hours:	03							
Course objectiv 1. To understar	es: nd the various antenna	parameters.									
2. Conduct exp	eriments to study the F	Radiation pattern of Ar	ntennas.								
3. Design diffe	rent types of antenna a	rrays and study the pat	rays and study the pattern characteristics (MATLAB)								
4. Design of M	MIC antennas like Pate	ch Antenna and study	the characteristics.								
Sl. No	Experiments										
1	Γο obtain the radiation	pattern of a Yagi-Uda	Antenna array and calculate	e its directivity							
2	To obtain the radiation pattern of a Dipole Antenna array and calculate its directivity.										
3	To calculate the apertur	re of a Dipole Antenna	e of a Dipole Antenna.								
4	To obtain the near and	far fields of a given an	tenna and compare the field	ls.							
5	To obtain the Radiation	pattern of a microstri	p antenna.								
6	Γo obtain the resonant	frequency of a Yagi-Uda /Dipole antenna.									
7	Γo obtain the bandwidt	h of a given Antenna.									
8 1	Plot 2-D and 3-D radiat	tion pattern of omnidirectional antenna using MATLAB.									
9 1	Design and implementa	ation of a broadside array using MATLAB.									
10 1	Design and implementa	ation of an endfire arra	y using MATLAB.								
]	Demonstration Exper	iments (For CIE)									
11]	Design of a Patch Ante	nna using HFSS Softw	/are.								
12	Design of a dipole Ante	enna using HFSS Software.									
Course outcome At the end of the	es: e course the student v	vill be able to:									
1. Analyze the	radiation pattern and c	haracteristics of anteni	na								
2. Ability to de	sign various antenna										
3. Ability to us	e different software too	ols to study antenna ch	aracteristics								
4. Analyze radi	ation pattern of linear	array antennas									

4. Analyze radiation pattern of linear array antennas

Suggested Learning Resources:

- 1. Antennas and Wave Propagation -John D Krauss, Ronald J Marhefka, Ahmad S Khan, 4th Edition,
- 2. McGraw Hill Education, 2013.
- 3. https://www.mathworks.com/help/antenna/
- 4. Help and demo files of the HFSS and MATLAB software

	CO-PO Mapping														
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	2	2											2	2	
CO2	3	3	3										3	3	
CO3	2	2	2	2	3								2	2	
CO4	2	2	2	2									2	2	
			•		•	•						•		•	

High-3, Medium-2, Low-1

MICROWAVES TOOLBOX

Course Code:	21ECL5084	CIE Marks:	50
Teaching Hours/Week (L:T:P:S):	0:0:2:0	SEE Marks:	50
Total Hours of Pedagogy:	13	Total Marks:	100
Credits:	01	Exam Hours:	03

Course objectives:

- Identification of microwave components/devices.
- Study basic principles of operation of microwave devices/ components

Sl. No	Experiments
1	V- I Characteristics of Gunn-diode.
2	Study of characteristics of Magic Tee
3	Coupling and Isolation characteristics of microstrip directional coupler.
4	Determination of power division of microstrip power divider.
5	Determination of resonance characteristics of microstrip ring resonator and computation of dielectric constant of the substrate.
6	Measurement of frequency, guide wavelength, power and attenuation in a microwave Test bench.
7	Study of characteristics of E plane Tee / H plane Tee.
8	To measure unknown impedance using Smith chart through test bench setup.
9	Measurement of VSWR and reflection coefficient and attenuation in a microwave test bench Setup.
10	Study propagation of wave using rectangular waveguide using MATLAB.
11	Study of impedance matching using MATLAB.
12	To calculate phase and group velocity using MATLAB.

Course outcomes:

At the end of the course the student will be able to:

- 1. Demonstrate the characteristics of microwave sources.
- 2. Demonstrate the characteristics of directional coupler
- 3. Study of microwave measurement procedure.
- 4. Apply MATLAB toolbox for study of microwaves phenomena.

1	17					2				L					
							CO-I	PO Ma	pping	5					
	PO1	PO2	PO3	PO4	PO5	PO6		PO8		PO10	PO11	PO12	PSO1	PSO2	PSO3
<u> </u>	-	2	2									2		2	
CO1	3	3	2									2	2	2	
CO2	3	3	3	3		2						1	2	2	
			_	_											
CO3	2	2	2	2	3								2	2	
CO4	2	2	2	2									2	2	
High-3	, Mediu	ım-2, L	ow-1												

TECHNOLOGICAL INNO								
Course Code:	21ECT601	CIE Marks:	50					
Teaching Hours/Week (L:T:P:S):	3:0:2:0							
Total Hours of Pedagogy:	52	Total Marks:	100					
Credits:	04	Exam Hours:	03					
Course objectives:								
1. Understand basic skills of Ma	•							
2. Understand the need for Entr								
3. Identify the Management fun								
4. Understand the Ideation Proc		ss Model.						
	Module-1		08 hrs					
Management: Nature and Function								
Levels of Management, Roles of	0 , 0	al Skills, Management &	Administration					
Management as a Science, Art & Pro								
(Selected topics of Chapter 1, Text 1								
Planning: Planning-Nature, Importa	•• •	Limitations of Planning; I	Decision Making					
Meaning, Types and Steps in Decisio	e							
(Selected topics from Chapters 4 & S	S, Text 1). L1,L2							
Teaching Learning Method:C	Chalk and Talk, PowerP	oint Presentation						
RBT Level:	L1, L2							
	Module-2	eristics Process of Organiz	07 hrs					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; Committees)	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer	nce only), Departmentalisat ntralization of Authority an	ing, Principles o ion, Committees					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer ruitment and Selection	nce only), Departmentalisat ntralization of Authority an	ing, Principles o ion, Committees					
Organizing and Staffing: Organizat Organizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 &	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer ruitment and Selection & 11, Text 1).	nce only), Departmentalisat ntralization of Authority an Process	ing, Principles o ion, Committees d Responsibility					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mea	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction,	ing, Principles o ion, Committees d Responsibility Giving Orders					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; Co Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mean Motivation-Nature of Motivation, Mean	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo	ing, Principles o ion, Committees d Responsibility Giving Orders ory and Herzberg					
Organizing and Staffing: Organizat Organizing, Span of Management (Meaning, Types of Committees; Co Staff"mg-Need and Importance, Rect (Selected topics from Chapters 7, 8 & Directing and Controlling: Meat Motivation-Nature of Motivation, Ma Two Factor Theory); Communica	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of	ing, Principles o ion, Committees d Responsibility Giving Orders ory and Herzberg'					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; Co Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mea Motivation-Nature of Motivation, Mea Two Factor Theory); Communica Leadership-Meaning, Characteristics	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approac	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of	ing, Principles o ion, Committees d Responsibility Giving Orders ory and Herzberg					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mean Motivation-Nature of Motivation, Ma Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to	Module-2 ation-Meaning, Charact (meaning and importar entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1).	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership.	ing, Principles o ion, Committees d Responsibility Giving Orders ory and Herzberg					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; Co Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mean Motivation-Nature of Motivation, Ma Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: C	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1). Chalk and Talk, PowerP	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership.	ing, Principles o ion, Committees d Responsibility Giving Orders ory and Herzberg					
Organizing and Staffing: Organiza Organizing, Span of Management (Meaning, Types of Committees; Co Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Mean Motivation-Nature of Motivation, Ma Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: C	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1). Chalk and Talk, PowerP L1, L2	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership.	ing, Principles o ion, Committees d Responsibility Giving Orders ry and Herzberg Communication					
Organizing and Staffing: OrganizaOrganizing, Span of Management (Meaning, Types of Committees; CaStaff"mg-Need and Importance, Reca(Selected topics from Chapters 7, 8 &Directing and Controlling: MeatMotivation-Nature of Motivation, MaTwo Factor Theory); CommunicaLeadership-Meaning, Characteristics(Selected topics from Chapters 15toTeaching Learning Method:RBT Level:Leadership	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1). Chalk and Talk, PowerP 1, L2 Module-3	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership.	ing, Principles o ion, Committees id Responsibility Giving Orders ory and Herzberg' Communication					
Organizing and Staffing: OrganizaOrganizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Meat Motivation-Nature of Motivation, Meat Two Factor Theory); Communicat Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: Leadership-Imagement (C RBT Level:Social Responsibilities of Busines	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approach 18and 9, Text 1). Chalk and Talk, PowerP L1, L2 Module-3 ss: Meaning of Socia	nce only), Departmentalisat ntralization of Authority an Process its of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership. Point Presentation	ing, Principles o ion, Committees id Responsibility Giving Orders ry and Herzberg' Communication					
Organizing and Staffing: OrganizaOrganizing, Span of Management (Meaning, Types of Committees; Ca Staff"mg-Need and Importance, Reca (Selected topics from Chapters 7, 8 & Directing and Controlling: Meat Motivation-Nature of Motivation, Ma Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: RBT Level:Social Responsibilities of Business Business towards Different Groups, S	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1). Chalk and Talk, PowerP 21, L2 Module-3 ss: Meaning of Socia Social Audit, Business	nce only), Departmentalisat ntralization of Authority an Process its of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership. Point Presentation	ing, Principles o ion, Committees id Responsibility Giving Orders ry and Herzberg' Communication					
Organizing and Staffing: OrganizaOrganizing, Span of Management (Meaning, Types of Committees; C Staff"mg-Need and Importance, Rec (Selected topics from Chapters 7, 8 & Directing and Controlling: Meat Motivation-Nature of Motivation, Meat Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: RBT Level:Social Responsibilities of Busines Susiness towards Different Groups, S (Selected topics from Chapter 3, Tex	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approach 18and 9, Text 1). Chalk and Talk, PowerP L1, L2 Module-3 ss: Meaning of Socia Social Audit, Business at 1).	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership. Point Presentation	ing, Principles of ion, Committees id Responsibility Giving Orders ory and Herzberg Communication					
Organizing and Staffing: OrganizaOrganizing, Span of Management (Meaning, Types of Committees; Ca Staff"mg-Need and Importance, Reca (Selected topics from Chapters 7, 8 & Directing and Controlling: Meat Motivation-Nature of Motivation, Ma Two Factor Theory); Communica Leadership-Meaning, Characteristics (Selected topics from Chapters 15to Teaching Learning Method: RBT Level:Social Responsibilities of Business Business towards Different Groups, S	Module-2 ation-Meaning, Charact (meaning and importan entralization Vs Decer ruitment and Selection & 11, Text 1). ning and Requiremen otivation Theories (Mas ation - Meaning, Imp s, Behavioural Approact 18and 9, Text 1). Chalk and Talk, PowerP 21, L2 Module-3 ss: Meaning of Socia Social Audit, Business at 1). Entrepreneur, Impo successful Entrepreneur Development models, E	nce only), Departmentalisat ntralization of Authority an Process ts of Effective Direction, slow's Need-Hierarchy Theo portance and Purposes of h of Leadership. Point Presentation 1 Responsibility, Social R Ethics and Corporate Gover ortance of Entrepreneursh ur, Classification of Entrepreneursh Categorian development	ing, Principles of ion, Committees id Responsibility Giving Orders ory and Herzberg Communication 08 hrs esponsibilities of nance ip, concepts of reneurs, Myths of					

Teaching Learning Method:	Chalk and Talk, PowerPoint Presentation	
RBT Level:	L1, L2	
	Module-4	08 hrs
•	ortance of Family Business, Contributions of Fa	•
Stages of Development of a Fa	mily Business, Characteristics of a Family-ow	ned Business in India
Various types of family business		
(Selected topics from Chapter 4,	(Page 71-75) Text 2).	
	y Analysis- Idea Generation; Creativity and Inno	vation; Identification of
	Entry Strategies; Marketing Feasibility.	
(Selected topics from Chapter 6()	Page No. 111-117) & Chapter 7(Page No. 140-14	42), Text 2)
Teaching Learning Method:	Chalk and Talk, Power point presentations	
RBT Level:	L1, L2	
	Module-5	08 hrs
Business model- Meaning, desig	gning, analyzing and improvising; Business Plar	n - Meaning, Scope an
Need; Financial, Marketing, Hu	aman Resource and Production/Service Plan; I	Business plan Formats
Project report preparation and pre-	esentation; Why some Business Plan fails?	
(Selected topics from Chapter 8 (Page No 159-164, Text 2)	
Teaching Learning Method:	Chalk and Talk, Power point presentations	
RBT Level:	RBT Level: L1, L2	
Course outcomes:		
At the end of the course the stu	dent will be able to:	
CO 1. Understand the fundament	tal concepts of Management and Entrepre- neurs	hip and opportunities i
order to setup a business		
CO 2. Identify the various organ	izations' architecture	
CO 3. Describe the functions of 1	Managers, Entrepreneurs and their social respons	sibilities
CO 4. Understand the component	ts in developing a business plan	
CO 5. Recognize the various sou	rces of funding and institutions supporting entrep	preneurs.
Suggested Learning Resources		
Text Books:		
1. Principles of Management - P.C 13:978-93-5260-5354.	C Tripathi, P.N Reddy, McGraw Hill Education, f	YhEdition, 2017. ISBN
2. Entrepreneurship Developme	ent Small Business Enterprises- Poomima M	Charantimath, Pearso
Education 2008, ISBN 978-81-77	758-260-4.	
3. Dynamics of Entrepreneurial I	Development and Management by Vasant Desai.	HPH 2007, ISBN: 978
81-8488-801-2.		
4. Robert D. Hisrich, Mathew J.	Manimala, Michael PPeters and DeanA. Shephe	erd, "Entrepreneurship"
S1h Edition, Tata Mc-Graw Hill	Publishing Co.Ltd New Delhi, 2012	
Reference Books:		
C	nt: An International, Innovation and Leadership McGraw Hill Education, I01h Edition 2016. ISBN	N- 978-93-392-2286-4
	asted A stivition in Class)/ Due stigal Daged leave	
Activity Based Learning (Sugg	ested Activities in Class)/ Practical Based lear	ning

	CO-PO Mapping														
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
High-	3, Medi	um-2, I	Low-1	•		•		•	•	•	•	•		•	<u> </u>

	GANIZATION & ARM	I MICROCONTROLLER	S					
Course Code:	21ECT602	CIE Marks:	50					
Teaching Hours/Week (L:T:P:S):	3:0:2:0	SEE Marks:	50					
Total Hours of Pedagogy:	52	Total Marks: 100						
Credits:	04	Exam Hours:	03					
Course objectives:			-					
1. to explain the basic organization of	of a computer system.							
2. to understand functioning of diffe	rent sub systems, such a	as processor, Input/output, an	nd memory.					
3. to describe the architectural featur	res and instructions of 3	2-bit microcontroller ARM	Cortex M3.					
4. to Program ARM Cortex M3 for a	different applications.							
5. to analyse the Thumb instruction	= =	ramming concepts.						
	Module-1		08 hrs					
Basic Structure of Computers: Bas	sic Operational Concept	s, Bus Structures, Performat	nce – Processor					
Clock, Basic Performance Equation,								
Input/Output Organization: Acces			Direct Memory					
Access, Buses, Interface Circuits, St			=					
		oint Presentation, YouTube						
0 0	L1, L2	,						
	Module-2		08 hrs					
Memory System: Basic Concepts,		lemories Read Only Memo						
		femories, Read Only Memo	iles, speed, size,					
and Cost Cache Memories – Manni	ng Functions Replacem	ent Algorithms Performance	e Considerations					
and Cost, Cache Memories – Mapping Basic Processing Unit: Some Funda		-						
Basic Processing Unit: Some Funda	amental Concepts, Exec	ution of a Complete Instruct	ion, Multiple Bus					
Basic Processing Unit : Some Funda Organization, Hard-wired Control, M	amental Concepts, Exec Micro programmed Cont	ution of a Complete Instruct trol. Basic concepts of pipel	ion, Multiple Bus ining, Text 1					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP	ution of a Complete Instruct	ion, Multiple Bus ining, Text 1					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2	ution of a Complete Instruct trol. Basic concepts of pipel	ion, Multiple Bus ining, Text 1 videos					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:CRBT Level:I	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube	ion, Multiple Bus ining, Text 1 videos 08 hrs					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:ORBT Level:IARM Embedded Systems: Introduction	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design philo	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philos	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: C RBT Level: I ARM Embedded Systems: Introduct System hardware – AMBA bus protect	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design philo pcol, ARM bus technolo	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:RBT Level:IARM Embedded Systems: Introdusystem hardware – AMBA bus protosoftware – Initialization (BOOT) code	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications.	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system					
Basic Processing Unit: Some Fundation, Hard-wired Control, MOrganization, Hard-wired Control, MTeaching Learning Method:RBT Level:IARM Embedded Systems: Introductsystem hardware – AMBA bus protoconsoftware – Initialization (BOOT) conARM Processor Fundamentals, ARM	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model,	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system					
Basic Processing Unit: Some FundaOrganization, Hard-wired Control, MTeaching Learning Method:RBT Level:IARM Embedded Systems: Introdusystem hardware – AMBA bus protosoftware – Initialization (BOOT) coordARM Processor Fundamentals, ARMPipeline, Exceptions, Interrupts and	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exte	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st ensions. Text 2	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register,					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: RBT Level: I ARM Embedded Systems: Introduction system hardware – AMBA bus protocol software – Initialization (BOOT) cool ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exte	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register,					
Basic Processing Unit: Some FundationOrganization, Hard-wired Control, MTeaching Learning Method:RBT Level:IARM Embedded Systems: Introductsystem hardware – AMBA bus protocsoftware – Initialization (BOOT) coordARM Processor Fundamentals, ARMPipeline, Exceptions, Interrupts andTeaching Learning Method:Construction<	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exte	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st ensions. Text 2	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register,					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: RBT Level: I ARM Embedded Systems: Introduction system hardware – AMBA bus protocom software – Initialization (BOOT) coord ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core extec Chalk and Talk, PowerP	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st ensions. Text 2	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register,					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: RBT Level: I ARM Embedded Systems: Introduction system hardware – AMBA bus protocol software – Initialization (BOOT) cool ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile bcol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core extec Chalk and Talk, PowerP L1, L2 Module-4	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E applications. registers, current program st ensions. Text 2 oint Presentation, YouTube	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register, videos 08 hrs					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: RBT Level: I ARM Embedded Systems: Introduction system hardware – AMBA bus protoconfiction (BOOT) confiction ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method: RBT Level:	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile ocol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core extec Chalk and Talk, PowerP L1, L2 Module-4 ction set: Introduction,	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E Applications. registers, current program st ensions. Text 2 oint Presentation, YouTube Data processing instructio	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register, videos 08 hrs ns, Load – Store					
Basic Processing Unit: Some Funda Organization, Hard-wired Control, MTeaching Learning Method:CRBT Level:IARM Embedded Systems: Introdu system hardware – AMBA bus proto software – Initialization (BOOT) con ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method:CRBT Level:IIntroduction to the ARM InstructI	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile bcol, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exter Chalk and Talk, PowerP L1, L2 Module-4 ction set: Introduction, tructions, Program stat	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E Applications. registers, current program st ensions. Text 2 oint Presentation, YouTube Data processing instructio	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register, videos 08 hrs ns, Load – Store					
Basic Processing Unit: Some Fundation, Hard-wired Control, M Organization, Hard-wired Control, M Teaching Learning Method: G RBT Level: I ARM Embedded Systems: Introduction (BOOT) controls G ARM Processor Fundamentals, ARM Pipeline, Exceptions, Interrupts and Teaching Learning Method: G RBT Level: I Introduction to the ARM Instruction, Software interrupt instruction, Software interrupt instruction, Software interrupt instruction and the set of the text of t	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile cool, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exter Chalk and Talk, PowerP L1, L2 Module-4 ction set: Introduction, tructions, Program stat xecution. Text 2	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E Applications. registers, current program st ensions. Text 2 oint Presentation, YouTube Data processing instructio	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register, videos 08 hrs ns, Load – Store pading constants,					
Basic Processing Unit: Some Fundation, Hard-wired Control, MOrganization, Hard-wired Control, MTeaching Learning Method:QRBT Level:IARM Embedded Systems: IntroductionGsystem hardware – AMBA bus protosoftware – Initialization (BOOT) controlARM Processor Fundamentals, ARMPipeline, Exceptions, Interrupts andGTeaching Learning Method:GRBT Level:IIntroduction to the ARM Instruction, Software interrupt instruction, Software interrupt instructional ETeaching Learning Method:GARMv5E extensions, Conditional ETeaching Learning Method:G	amental Concepts, Exec Micro programmed Cont Chalk and Talk, PowerP L1, L2 Module-3 ction, RISC design phile cool, ARM bus technolo de, Operating System, A M core dataflow model, Vector Table, Core exter Chalk and Talk, PowerP L1, L2 Module-4 ction set: Introduction, tructions, Program stat xecution. Text 2	ution of a Complete Instruct trol. Basic concepts of pipeli oint Presentation, YouTube osophy, ARM design philoso ogy, Memory, Peripherals, E Applications. registers, current program st ensions. Text 2 oint Presentation, YouTube Data processing instructio us register instructions, Lo	ion, Multiple Bus ining, Text 1 videos 08 hrs ophy, Embedded mbedded system tatus register, videos 08 hrs ns, Load – Store pading constants,					

Introduction to the THUMB instruction set: Introduction, THUMB register usage, ARM – THUMB interworking, Other branch instructions, Data processing instructions, Stack instructions, Software interrupt instructions.

Efficient C Programming: Overview of C Compilers and optimization, Basic C Data types, C looping structures. Text 2

Teaching Learning Method:	Chalk and Talk, Power point presentations, Programming assignments
RBT Level:	RBT Level: L1, L2, L3

PRACTICAL COMPONENT OF IPCC

Conduct the following experiments by writing Assembly Language Program (ALP) using ARM Cortex M3 Registers using an evaluation board/simulator and the required software tool

Sl. No.	Experiments	12 hrs
1.	Write an ALP to find the sum of first 10 integer numbers.	
2.	Write an ALP to calculate the value of the polynomial function.	
3.	Write an ALP to store data in desired Memory location.	
4.	Write a C program to Output the message using UART of LPC1768.	
5.	Write a C Program to interface LED using LPC 1768.	
6.	Write a C Program to interface Relay using LPC 1768.	
7.	Write a C Program for DC motor/Stepper motor rotation using LPC 1768.	
8.	Write a C Program to interface a DAC and generate Triangular and Square wa	aveforms.
9.	Write a C program to demonstrate the use of an External interrupt in LPC 176	58

Demonstration Experiments (For CIE only not for SEE)

Conduct the following experiments on an ARM CORTEX M3 evaluation board using evaluation version of Embedded 'C' & Keil µvision-4 tool/compiler.

10.	Write a C program to interface a Real Time Clock (RTC) of LPC 1768.
11.	Write a program to read on-chip ADC value and display it on UART terminal using LPC 1768
12.	Write a C program to interface Keypad using LPC 1768.

Course outcomes:

At the end of the course the student will be able to:

CO 1: Understand the basic structure and Input output organization of a computer system.

CO 2: Explain functioning of different sub systems, such as processor, Input/output, and memory.

CO 3: Describe the architectural features and instructions of 32-bit microcontroller ARM Cortex M3.

CO 4: Apply the instruction set to Program ARM Cortex M3 for different applications.

CO5: Analyse Thumb Instruction set and C-Programming Concepts to Program ARM Cortex M3.

Suggested Learning Resources:

Text Books:

1. Carl Hamacher, Zvonko Vranesic, Safwat Zaky, Computer Organization, 5th Edition, Tata McGraw Hill, 2002. (Listed topics only from Chapters 1, 2, 4, 5, 8).

2. Andrew N Sloss, Dominic System and Chris Wright, "ARM System Developers Guide", Elsevier, Morgan Kaufman publisher, 1st Edition, 2008

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Programming Assignments / Mini Projects can be given to improve programming skills

	CO-PO Mapping														
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2												3	
CO2	3	2												3	
CO3	3	2												3	
CO4	3	2	2		2		1		1					3	
CO5	3	2	2		2		1		1					3	
High-3	, Mediı	um-2, L	low-1												

	V]	LSI DESIGN AND '	resting		
Course Code:		21ECT603	CIE	50	
Teaching Hours/Week (L:T:P	?: S):	3:0:0	SEE	Marks:	50
Total Hours of Pedagogy:		39	Tota	Marks:	100
Credits:		03	Exar	n Hours:	3
Course objectives: 1. Impart knowledge of MOS ta	ransisto	r theory and CMOS	technology		
2. Learn the operation principle		•			
3. Infer the operation of Semico		•			
4. Demonstrate the concept of		-			
		Module-1			8 Hrs
Introduction: A Brief History,	MOS	Fransistors, CMOS L	ogic (1.1 to 1.4	of TEXT1)	
MOS Transistor Theory: Intro	oductio	n, Long-channel I-V	Characteristics,	Non-ideal I-	V Effects, DC
Transfer Characteristics (2.1, 2	.2, 2.4 a	and 2.5 of TEXT1).			
Teaching Learning Method:	Chalk	and talk method, Po	werPoint Prese	ntation, YouT	ube videos,
RBT Level:		s on transistor worki			
	Self-s	tudy topics: MOSFE	T Scaling and S	mall-Geomet	try Effects
	RBT	Level: L1, L2, L3			
		Module-2			08 Hrs
Fabrication: CMOS Fabrication	on and	Layout, Introduction	, CMOS Techn	ologies, Layo	out Design Rules,
(1.5 and 3.1 to 3.3 of TEXT1).					
Delay: Introduction, Transient	Respon	se, RC Delay Model	, Linear Delay I	Model, Logica	al Efforts of Paths
(4.1 to 4.5 of TEXT1, except su	ub-secti	ons 4.3.7, 4.4.5, 4.4.	6, 4.5.5 and 4.5	.6).	
Teaching Learning Method:		and talk method, Po			ube videos,
RBT Level:		s on fabrication			
	Self-s	tudy topics: Layouts	of complex des	ign using Eul	er's method
	RBT	Level: L1, L2, L3			
		Module-3			08 Hrs
Semiconductor Memories: Int					
Access Memory (SRAM), Non	volatile	e Memory, Flash Mer	nory, Ferroelec	tric Random A	Access Memory
(FRAM) (10.1 to 10.6 of TEXT	Г2)				
Teaching Learning Method: RBT Level:		and talk method, Po ard cell memory Des		ntation, YouT	ube videos on
		tudy topics: Memory	0		
	RBT	Level: L1, L2, L3			
		Module-4			08 Hrs
Faults in digital circuits: Faile	ures and	l faults, Modelling of	f faults,		
Temporary faults Test genera	ation fo	or combinational log	gic circuits : Fai	ult diagnosis	of digital circuits,
test generation techniques for o	combina	ational circuits, Dete	ction of multipl	e faults in co	mbinational logic
circuits.					
(1.1 to 1.3, 2.1 to 2.3 of TEXT:	3)				
•	<u> </u>	and talk method, Po	werPoint Prese	ntation, YouT	ube videos,
RBT Level:		s on testing algorithn			,
		tudy topics: Testable	-		
		Level: L1, L2, L3			
Temporary faults Test generation techniques for circuits. (1.1 to 1.3, 2.1 to 2.3 of TEXT: Teaching Learning Method:	ation for combination 3) Chalk videos Self-s	ational circuits, Dete and talk method, Po s on testing algorithm tudy topics: Testable	gic circuits: Fau ction of multipl werPoint Presents for test gener	e faults in co ntation, YouT ation	mbinational logi ube videos,

	Mo	dule-5							07	Hrs
Test generation for sequential circuits: Testing of sequential circuits as iterative combinational circuits									circuits,	
state table verification, test generation based on circuits structure, functional fault models, test										
generation based on functional	fault model	s.								
Design of testable sequential	circuits: Co	ntrolla	bility a	and Ol	oservab	oility, A	dhoc de	esign ru	les, des	ign of
diagnosable sequential circuits			•			•		-		-
scan. (4.1 to 4.5, 5.1 to 5.7 of T	-		1	,	,				1 /1	
Teaching Learning Method:	Chalk and	talk m	ethod/	Power	· point	present	ation. Y	ωTube	e videos	
RBT Level:	Self-study							041404		
	RBT Leve	-					•••			
Course outcomes:		,								
At the end of the course the s	tudent will	be abl	e to:							
CO1. Demonstrate understandi	ng of MOS	transis	tor the	ory, C	MOS f	abricat	ion flow	v and te	chnolog	gy
scaling.										
CO2. Draw the basic gates usi	ng the stick	and lay	yout di	agram	with t	he knov	wledge	of phys	ical des	ign
aspects.										
CO3. Interpret memory eleme	0		0							
CO4. Interpret testing and testa	•				-	-				
CO5. Interpret testing and testa		in Sec	luentia	ll logi	c design	1.				
Suggested Learning Resource Text Books:	es:									
1: "CMOS VLSI Design- A Ci	revite and S	uctome	Dorgo	octivo	", Noil	нем	asta an	d David	Mone	.7
Harris 4 th Edition, Pearson Edu			reisp		, 10011		csic, all	u Davi		у
2: "CMOS Digital Integrated C			nd Des	sign".	Sung N	/Io Kan	9 & Yo	suf Leb	lebici.	Third
Edition, Tata McGraw-Hill, 20				,	2		8 - 1 -	201 200	,	
3: "Digital Circuit Testing and		, Lala I	Parag	K, Ne	w York	, Acad	emic Pr	ess, 199	97	
Reference Books:		·	U	,		,		,		
1: "Basic VLSI Design", Doug	las A Puckn	ell, Ka	mran I	Eshrag	hian, 3	rd Edit	ion, Pre	ntice H	all of I	ndia
publication, 2005.										
2: "Essential of Electronic Test	ing for Digi	tal, Me	emory	and M	lixed Si	ignal C	ircuits"	, Vishw	ani D	
Agarwal, Springer, 2002.										
Activity Based Learning (Sug										
1: Model displayed for clear understanding of fabrication process of MOS transistor										
2: Practise session can be held to understand the significance of various layers in MOS process, with the										
help of coloured layouts										
CO-PO Mapping										
P01 P02 P03 P04	P05 P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1 3 3 3	2							1	1	1
CO2 3 3 2 CO3 3 2 1								1	1	1
CO3 3 2 1 CO4 3 3 2								1	1	1
CO5 3 2 3								1	1	1

High-3, Medium-2, Low-1

	ARTIFICIAL NEURAL	NETWORK	
Course Code:	21ECT6041	CIE Marks:	50
Teaching Hours/Week (L:T:P	:S): 3:0:0:0	SEE Marks:	50
Total Hours of Pedagogy:	39	Total Marks:	100
Credits:	03	Exam Hours:	3
Course objectives:			
1. To provide a strong four	ndation of fundamental conce	epts and structures in Neura	l Networks.
2. To understand the Anal	ysis of different techniques an	nd algorithms in Neural Net	tworks.
3. To study the concepts o	f setting parameters and mult	ilayered Networks.	
4. To understand the conce	epts of Prediction, Polynomia	ll Neural Networks.	
5. To analyze the Optimization	ation techniques in Neural Ne	etworks	
6. To enable the student to	apply these techniques in ap	plications which involve ne	ural models.
	Module-1	1	08 hrs
Introduction, Fundamental co	ncepts and models of Art	ificial Neural Network, H	Biological Neural
Networks, structure and funct	-		-
network, Neural learning proce		,	6
Teaching Learning Method:			
RBT Level:	L1, L2		
	Module-2		09 hrs
Supervised Learning for sing		on linear senarability Pe	
Algorithm, Delta rule. Super	•	· ·	
preliminaries, Back propagation	-	layer network. manner	er disermination,
	i, setting parameter values.		
Teaching Learning Method:			
RBT Level:	L1, L2		0.01
	Module-3	· - · - ·	08 hrs
Prediction networks: Introducti			
Polynomial networks: Higher	order network, Sigma-pi ne	etwork, Function link arch	itecture, Pi-sigma
network			
Teaching Learning Method:			
RBT Level:	L1, L2		
	Module-4		08 hrs
Unsupervised learning: Winn	er take all networks. Hamm	ning networks, Maxnet, Si	mple competitive
learning, Hebb rule,			
Optimization Methods: Hop file	ed networks, Travelling Sales	person problem, Iterated C	Bradient Descent
Teaching Learning Method:	, ,	· · ·	
RBT Level:	L1, L2		
	Module-5		06 hrs
Introduction to Neural Network		r Machine. Generative Adv	
Convolutional Neural Network	e 11		
Case studies on neural network	0 1	e e	tion
Weather Forecasting, Voice Re	•	inton, stock murket i ieule	~~~
,, sumer i orecusting, voice Re	~~5 ^{mmon}		

Teaching Learning Method:	
RBT Level:	L2, L3, L4
Course outcomes:	
At the end of the course the st	udent will be able to:
CO1. Understand the basic con	ncepts of Neural Networks.
CO2. Analysis and developme	ent of different techniques in neural networks.
CO3. Analysis the concepts of	f Prediction Networks.
CO4. Understand and analysis	s of the concepts of Polynomial networks in Artificial
CO5. Use different optimization application.	ion, machine learning technique for different model and enveloping the
Suggested Learning Resource	s:
Text Books:	
1. Kishan Mehrotra, C. K. 2007.	Mohan, Sanjay Ranka, Penram, "Elements of Artificial Neural Networks",
2. J. Zurada, Jaico, "Introd	uction to Artificial Neural Systems", 2003.
3. Neural Networks A Cla Second Edition 2019	ssroom Approach- Satish Kumar, McGraw Hill Education (India) Pvt. Ltd,
4. Mohamad H Hassoun "	Fundamentals of Artificial Neural Networks, PHI 2019 edition
Reference Books	
1. Simon Hayking, "Neura	l Networks: A Comprehensive Foundation",2 nd Edition, PHI.
	mentals of Neural Networks: Architecture, Algorithms and Applications",
Web Links: nptl.iitm.ac.in	
	gested Activities in Class)/ Practical Based learning
Activity 1: Project on Voice re-	cognition system
Activity 2: Stock Market Predic	ction

	CO-PO Mapping														
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	3	2	2	2	1	-	-	2	-	-	-	3	3	3	2
CO2	3	3	2	2	1	-	-	2	-	-	-	3	3	3	2
CO3	3	2	2	2	1	-	-	2	-	-	-	3	3	3	2
CO4	3	3	2	2	2	-	-	2	-	-	-	3	3	3	2
CO5	3	1	1	2	1	-	-	2	-	-	-	3	3	3	2

High-3, Medium-2, Low-1

	CRYPTOGRA	РНҮ	
Course Code:	21ECT6042	CIE Marks:	40+5+5
Teaching Hours/Week (L:T:P:		SEE Marks:	50
Total Hours of Pedagogy:	40	Total Marks:	100
Credits:	3	Exam Hours:	03
Course objectives:			
This course will enable students	s to:		
• Preparation: To prepare stude	nts with fundamental know	vledge/ overview in the f	ield of Information
Security with knowledge of mat		-	
• Core Competence: To equip s			y delivering the
basics of symmetric key and pul			=
technique			
	Module-1		08 hrs
Basic Concepts of Number Th	eory and Finite Fields: D	vivisibility and The Divis	sion Algorithm
Euclidean algorithm, Modular a	rithmetic, Groups, Rings a	nd Fields, Finite fields o	of the form GF(p),
Polynomial Arithmetic, Finite F	Fields of the Form GF(2m)	(Text 1: Chapter 3)	
Teaching Learning Method:	Chalk and Talk, YouTube	videos, Flipped Class T	Technique
8 8	Programming on impleme		-
	inverse, Finite fields of the		=
			=
RBT Level:	inverse, Finite fields of the		=
RBT Level:	inverse, Finite fields of the GF(2m).		=
RBT Level: Introduction: Computer Securi	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2	e form GF(p), construct	08 hrs
	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for I	e form GF(p), construction	08 hrs 1: Chapter 1)
Introduction: Computer Securi	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for I	e form GF(p), construction	08 hrs 1: Chapter 1)
Introduction: Computer Securi Classical Encryption Technique	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for 1 ues: Symmetric cipher mod	e form GF(p), construction Network Security (Text del, Substitution techniq	08 hrs 1: Chapter 1) ues, Transposition
Introduction : Computer Securi Classical Encryption Techniq techniques (Text 1: Chapter 1)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for 1 ues: Symmetric cipher mod	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs.
Introduction : Computer Securi Classical Encryption Techniqu techniques (Text 1: Chapter 1)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for 1 ues : Symmetric cipher mod	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques.
Introduction : Computer Securi Classical Encryption Techniqu techniques (Text 1: Chapter 1)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 Ity Concepts, A Model for E ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques.
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method:	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques.
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method:	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level:	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition te y Mechanisms, Services encryption standard (DE 2, 3, 4)	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2:
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section1, 2) The AES Cipher. (inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition te y Mechanisms, Services encryption standard (DE 2, 3, 4)	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2:
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section1, 2) The AES Cipher. (More on Number Theory: Prin	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for L ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section me Numbers, Fermat's and Chalk and Talk, YouTube	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services encryption standard (DE 2, 3, 4) l Euler's theorem, discre	08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2: te logarithm. (Text 1: Cechnique and PPTs.
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section 1, 2) The AES Cipher. (More on Number Theory: Prin Chapter 7: Section 1, 2, 5)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section me Numbers, Fermat's and Chalk and Talk, YouTube Implementation of SDES	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services encryption standard (DE 2, 3, 4) Euler's theorem, discrete e videos, Flipped Class T using programming lang	08 hrs 08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2: te logarithm. (Text 1: Cechnique and PPTs. guages like
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section 1, 2) The AES Cipher. (More on Number Theory: Prin Chapter 7: Section 1, 2, 5)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section me Numbers, Fermat's and Chalk and Talk, YouTube Implementation of SDES C++/Python/Java/Scilab. S	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services encryption standard (DE 2, 3, 4) Euler's theorem, discrete e videos, Flipped Class T using programming lang	08 hrs 08 hrs 1: Chapter 1) ues, Transposition Cechnique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2: te logarithm. (Text 1: Cechnique and PPTs. guages like
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section 1, 2) The AES Cipher. (* More on Number Theory: Prin Chapter 7: Section 1, 2, 5) Teaching Learning Method:	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 Ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section me Numbers, Fermat's and Chalk and Talk, YouTube Implementation of SDES C++/Python/Java/Scilab. S differential attacks	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services encryption standard (DE 2, 3, 4) Euler's theorem, discrete e videos, Flipped Class T using programming lang	08 hrs 1: Chapter 1) ues, Transposition Technique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2: te logarithm. (Text 1: Technique and PPTs. guages like
Introduction: Computer Securi Classical Encryption Technique techniques (Text 1: Chapter 1) Teaching Learning Method: RBT Level: Block Ciphers: Traditional Blo Section1, 2) The AES Cipher. (* More on Number Theory: Prin Chapter 7: Section 1, 2, 5)	inverse, Finite fields of the GF(2m). L1, L2, L3 Module-2 ity Concepts, A Model for D ues: Symmetric cipher mod Chalk and Talk, YouTube Programming on Substitut Self-study topics: Security L1, L2, L3 Module-3 ck Cipher structure, Data e Text 1: Chapter 4: Section me Numbers, Fermat's and Chalk and Talk, YouTube Implementation of SDES C++/Python/Java/Scilab. S	e form GF(p), construction Network Security (Text del, Substitution techniq e videos, Flipped Class T tion and Transposition to y Mechanisms, Services encryption standard (DE 2, 3, 4) Euler's theorem, discrete e videos, Flipped Class T using programming lang	08 hrs 1: Chapter 1) ues, Transposition Technique and PPTs. echniques. and Attacks. 08 hrs S) (Text 1: Chapter 2: te logarithm. (Text 1: Technique and PPTs. guages like

Hellman	Principles of Public-Key Cryptosystems, The RSA	
	Arithmetic, Elliptic Curve Cryptography (Text 1: C	hapter 8, Chapter 9:
Section 1, 3, 4)		
Teaching Learning Method:	Chalk and Talk, YouTube videos, Flipped Class	Fechnique and PPTs.
8 8	Implementation of Asymmetric key algorithms us	-
	languages like C++/Python/Java/Scilab. Numeric	01 0 0
	Curve Cryptography	1 1
RBT Level:	L1, L2, L	
	Module-5	08 hrs
Pseudo-Random-Sequence G	enerators and Stream Ciphers:	I
-	s, Linear Feedback Shift Registers, Design and ana	lysis of stream
ciphers, Stream ciphers using L	FSRs, A5, Hughes XPD/KPD, Nanoteq, Rambuta	n, Additive generators
Gifford, Algorithm M, PKZIP	(Text 2: Chapter 16)	-
Teaching Learning Method:	Chalk and Talk, YouTube videos, Flipped Class	Fechnique and PPTs.
	Implementation of simple stream ciphers using pr	rogramming language
	like C++/Python/Java/Scilab.	
RBT Level:	L1, L2, L3	
Course outcomes:		
At the end of the course, the s	tudent will be able to:	
At the end of the course the stu	dent will be able to:	
1. Explain traditional cryptogra	phic algorithms of encryption and decryption proc	ess.
2. Use symmetric and asymmetric	ric cryptography algorithms to encrypt and decryp	t the data.
3. Apply concepts of modern al	gebra in cryptography algorithms.	
4. Design pseudo random seque	ence generation algorithms for stream cipher syster	ns.
Suggested Learning Resource	es:	
Text Books:		
1. William Stallings, "Cryptog	raphy and Network Security Principles and Practic	e", Pearson Education
Inc., 6th Edition, 2014, ISBN: 9	978-93-325-1877-3	
2. Bruce Schneier, "Applied Cr	yptography Protocols, Algorithms, and Source cod	e in C", Wiley
Publications, 2nd Edition, ISBN	N: 9971-51-348-X.	
Reference Books:		
1. Cryptography and Network S	Security, Behrouz A Forouzan, TMH, 2007.	
2. Cryptography and Network S	Security, Atul Kahate, TMH, 2003	
Weblink:		
https://nptel.ac.in/courses/1061	05031	
1 1	gested Activities in Class)/ Practical Based learn	 ning
	ini Projects can be given to improve programming	0

	CO-PO Mapping														
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1															
CO2															
CO3															
CO4															
C05															
High-3	, Medi	um-2, 🛛	Low-1												

	PY	THON PROGRA	MMING	
Course Code:		21ECT6043	CIE Marks:	50
Teaching Hours/Week (L:T:P	P:S):	3:0:0:0	SEE Marks:	50
Total Hours of Pedagogy:		40	Total Marks:	100
Credits:		3	Exam Hours:	03
Course objectives:				
1. To acquire the fundame	entals of I	Python programmi	ng language.	
2. To attain an understand	ing of fu	nctions and collect	ion types.	
3. To familiarize the conce	epts of se	equence types, data	structures, and error han	dling in Python.
4. To realize the concepts	of object	oriented in Python	n.	
_	-	=	ng and regular expressior	18.
5		dule-1		08 hrs
Introduction: Introducing Pyth	hon. Setti	ing Up Python in V	Vindows, introducing IDI	LE.
Parts of Python programming		• • •	•	
operators, datatypes-Built-in d	-			-
statements.	atatypes,	sequences in 1 ye		nto, input una o'atput
Control Flow - if, if-elif-else	while	loop for loop in	finite loon break conti	nue return and nass
statements.	, while	100p, 101 100p, 111	mile loop, bleak, contr	nue, return, and pass
Teaching Learning Method:	Challe	and Talk, Power Po	int Presentation	
			Sint Presentation	
DDT L arrol		12		
RBT Level:	L1, L2,			001
	Mo	odule-2	1 4 4 77	08 hrs
Functions - Defining Function	Mo is, Calling	odule-2 g Functions, positio		d Arguments, Default
Functions - Defining Function Arguments, Variable-length a	Mo is, Calling	odule-2 g Functions, positio		d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators.	Mo ns, Calling argument	odule-2 g Functions, positio s, Recursive Func	ctions, Anonymous Fund	d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B	Mo is, Calling argument asic oper	odule-2 g Functions, positions, positions, Recursive Functions, built-in me	ctions, Anonymous Fund	d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method:	Mo ns, Calling argument asic oper Chalk a	odule-2 g Functions, positions, Recursive Func- trations, built-in method and Talk, Power Po	ctions, Anonymous Fund	d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B	Mo is, Calling argument asic oper	odule-2 g Functions, positions, Recursive Func- trations, built-in method and Talk, Power Po	ctions, Anonymous Fund	d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method:	Mo as, Calling argument asic oper Chalk a L1, L2,	odule-2 g Functions, positions, Recursive Func- trations, built-in method and Talk, Power Po	ctions, Anonymous Fund	d Arguments, Default
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method:	Mo ns, Calling argument asic oper Chalk a L1, L2, Mo	odule-2 g Functions, positions, Recursive Func- rations, built-in mer and Talk, Power Po and Talk, Power Po a L3 odule-3	etions, Anonymous Fund thods, del statement. int Presentation	d Arguments, Default ctions, and Function 08 hrs
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level:	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu	odule-2 g Functions, positions, Recursive Func- rations, built-in me and Talk, Power Po and Talk, Power Po bule-3 ples, Accessing the	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples,
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Creation	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary	dule-2 g Functions, positions, Recursive Func- rations, built-in mer- and Talk, Power Po- and Talk, Power Po- built-3 ples, Accessing the methods, using for	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples,
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Cree Operations on Dictionaries, Di	Mo ns, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Dio	pdule-2 g Functions, positions, positions, Recursive Functions, built-in mer and Talk, Power Post L3 pdule-3 ples, Accessing the methods, using for ctionary,	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Cree Operations on Dictionaries, Di dictionaries, Converting Strings	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis	bdule-2 g Functions, positions, Recursive Func- rations, built-in mer- and Talk, Power Po- L3 bdule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples.
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Cree Operations on Dictionaries, Di dictionaries, Converting Strings Data Structures in Python: Li	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis	bdule-2 g Functions, positions, Recursive Func- rations, built-in mer- and Talk, Power Po- L3 bdule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples.
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Creation Operations on Dictionaries, Didictionaries, Converting Strings Data Structures in Python: List Exceptions: Errors in a Python	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis hon Prog	bdule-2 g Functions, positions, Recursive Func- rations, built-in mer- and Talk, Power Po- L3 bdule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues	ctions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples.
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Cree Operations on Dictionaries, Di dictionaries, Converting Strings Data Structures in Python: Li Exceptions: Errors in a Pyth Exceptions.	Mo ns, Calling argument asic oper Chalk a L1, L2, Mo eating Tuj ictionary s into Dio inked Lis hon Prog	pdule-2 g Functions, positions, Recursive Func- ations, built-in mer- and Talk, Power Po- and Talk, Power Po- bule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues gram, Exception	ctions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples.
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Creation Operations on Dictionaries, Di- dictionaries, Converting Strings Data Structures in Python: Li- Exceptions: Errors in a Pyth Exceptions. Teaching Learning Method:	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis hon Prog Chalk a L1, L2,	pdule-2 g Functions, positions, Recursive Func- ations, built-in mer- and Talk, Power Po- and Talk, Power Po- bule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues gram, Exception	ctions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, converting lists into Examples.
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Creation Operations on Dictionaries, Di- dictionaries, Converting Strings Data Structures in Python: Li- Exceptions: Errors in a Pyth Exceptions. Teaching Learning Method:	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis hon Prog Chalk a L1, L2, Mo	bdule-2 g Functions, positions, positions, Recursive Func- rations, built-in mer- and Talk, Power Po- and Talk, Power Po- ples, Accessing the methods, using for ctionary, sts, Stacks, Queuess gram, Exception and Talk, PowerPoin L3 bdule-4	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples. Block, User Defined 08 hrs
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Creation Operations on Dictionaries, Di- dictionaries, Converting Strings Data Structures in Python: Li- Exceptions: Errors in a Pyth Exceptions. Teaching Learning Method: RBT Level: Object Oriented Programmin	Mo ns, Calling argument asic oper Chalk a L1, L2, Mo eating Tuj ictionary s into Dio inked Lis hon Prog Chalk a L1, L2, Mo ng in Pyt	dule-2 g Functions, positions, positions, Recursive Func- entions, built-in mean and Talk, Power Poon L3 dule-3 ples, Accessing the methods, using for ctionary, sts, Stacks, Queues gram, Exception L3 dule-4 thon: Features of C	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except int Presentation	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples. Block, User Defined 08 hrs ming System (OOPS),
Functions - Defining Function Arguments, Variable-length a Decorators. Strings and Lists: Creation, B Teaching Learning Method: RBT Level: Tuples, and Dictionaries: Cree Operations on Dictionaries, Di dictionaries, Converting Strings Data Structures in Python: Li Exceptions: Errors in a Pyth Exceptions. Teaching Learning Method: RBT Level:	Mo as, Calling argument asic oper Chalk a L1, L2, Mo eating Tu ictionary s into Did inked Lis hon Prog Chalk a L1, L2, Mo ng in Pyt ariable, co	odule-2 g Functions, positions, positions, built-in means rations, built-in means and Talk, Power Position and Talk, Power Position ples, Accessing the methods, using for citionary, sts, Stacks, Queuess gram, Exception and Talk, PowerPosition and Talk, PowerPosition	etions, Anonymous Fund thods, del statement. int Presentation e Tuple Elements, Basic be loop with dictionaries , Deques. Programming I Handling, The Except int Presentation	d Arguments, Default ctions, and Function 08 hrs Operations on Tuples, c, converting lists into Examples. Block, User Defined 08 hrs ming System (OOPS),

Inheritance and Polymorphism: Constructors in Inheritance, overriding Super class constructors and methods, The super() method, Types of Inheritance: Single/Multiple, Method Resolution order, Polymorphism, Operator Overloading, Method overloading, Method Overriding. Programming Examples

	Module-5	08 hrs
RBT Level:	L1, L2, L3	
Teaching Learning Method:	Chalk and Talk, PowerPoint Presentation	

Files in Python: Types of files, Opening and closing file, Working with Text files, Working with Binary Files, with statements, Pickle in Python, The seek() and tell() methods, Random accessing Binary files, zipping, and unzipping Files, reading and writing to CSV files.

Regular Expressions: Regular Expression, Sequence Characters in Regular Expression, Quantifiers in Regular Expression, Special Characters in Regular Expression, Using Regular Expression on Files, Retrieving Information from a HTML File.

Teaching Learning Method:	Chalk and Talk, Power Point Presentation
RBT Level:	L1, L2, L3

Course outcomes:

At the end of the course, the student will be able to:

CO1. Apply the knowledge of Python scripting elements, Python constructs, datatypes, to solve engineering problems.

CO2. Identify the problem to apply the concepts of control structures, functions and error handling to solve them using the Python programming language

CO3. Apply the knowledge of Python and use the language scripting elements to manage the data, build the data structures, and handle errors.

CO4. Designing the solution to real-world problems through object-oriented concepts such as Inheritance, Polymorphism, and operator overloading.

CO5. Demonstrating the concepts of file handling and regular expressions

Suggested Learning Resources:

Text Books:

1: Core Python Programming: Dr. R. Nageshwara Rao, Dream Tech Press, 2018

2: Introduction to Python Programming, Gowrishankar S, Veena A, CRC Press, 2019

Reference Books:

1: Think Python, Allen Downey, Green Tea Press.

2: Core Python Programming, W.Chun, Pearson.

3: Introduction to Python, Kenneth A. Lambert, Cengage

4: Learning Python, Mark Lutz, Orielly

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Activity 1: Group activity for a group of 4 or 5 students -5 marks

Activity 2: Two assignments are evaluated for 5 marks: Assignment1 – From Unit 1 and 2, Assignment2 from units 3,4 and 5

	CO-PO Mapping														
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	2	1	1	1				1					2		
CO2	2	2	3	1	2			1					2		
CO3	2	3	3	2	2			1					2		
CO4	2	3	3	1	2			1					2		
C05	1	3	2	1	2			1					2		
High-3	B, Medi	um-2,	Low-1												

MI	CRO ELECTRO MECHANICA	AL SYSTEMS	
Course Code:	21ECT6044	CIE Marks:	50
Teaching Hours/Week (L:T:P	:S): 3: 0: 0:1	SEE Marks:	50
Total Hours of Pedagogy:	40	Total Marks:	100
Credits:	03	Exam Hours:	03
Course objectives:			
1. Preparation: To prepare	students with fundamental know	wledge/ overview in the field	eld of Micro
Electro Mechanical System	ns.		
2. Core Competence: To eq	uip students with a basic foundat	ion in electronic engineering	g, mechanical
engineering, electrical eng	gineering, chemistry, physics and	l mathematics fundamentals	required for
comprehending the operati	ion and application of MEMS circ	uits, design.	
3. Professionalism & Lear	ning Environment: To inculcat	e in students an ethical an	d professiona
attitude by providing an	academic environment inclusive	e of effective communication	on, teamwork.
ability to relate engineering	ng issues to a broader social con	ntext, and life-long learning	g needed for a
successful professional car	reer.		
	Module 1		08 hrs
Overview of MEMS and Mic	crosystems: MEMS and Microsys	stem, Typical MEMS and M	licrosystems
Products, Evolution of Microfa	abrication, Microsystems and Mi	croelectronics, Multidiscipli	nary Nature
of Microsystems, Miniaturizatio	on, Applications and Markets.		
Text1:1.1,1.2,1.3,1.4,1.5,1.6,1.	7,1.8,1.9		
Text1:1.1,1.2,1.3,1.4,1.5,1.6,1. ² Teaching Learning Method:		ion of MEMS products and a	applications.
Teaching Learning Method:	7,1.8,1.9 Chalk and talk method, Animat L1, L2, L3	ion of MEMS products and a	applications.
Teaching Learning Method:	Chalk and talk method, Animat	ion of MEMS products and a	applications.
Teaching Learning Method: RBT Level:	Chalk and talk method, Animat L1, L2, L3	-	08 hrs
Teaching Learning Method: RBT Level: Working Principles of Micros	Chalk and talk method, Animat L1, L2, L3 Module 2 systems: Introduction, Microsense	ors, Micro actuation, MEMS	08 hrs
Teaching Learning Method: RBT Level: Working Principles of Micros actuators, Micro accelerometers	Chalk and talk method, Animat L1, L2, L3 Module 2 systems: Introduction, Microsense s, Microfluidics.Text1: 2.1,2.2,2.3	ors, Micro actuation, MEMS 3,2.4,2.5,2.6	08 hrs with Micro
Teaching Learning Method: RBT Level: Working Principles of Micros actuators, Micro accelerometers Engineering Science for Mic	Chalk and talk method, Animat L1, L2, L3 Module 2 systems: Introduction, Microsense	ors, Micro actuation, MEMS 3,2.4,2.5,2.6 ation: Introduction, Atomic	08 hrs with Micro Structure of
Teaching Learning Method: RBT Level: Working Principles of Micros actuators, Micro accelerometers Engineering Science for Micros	Chalk and talk method, Animat L1, L2, L3 Module 2 systems: Introduction, Microsense s, Microfluidics.Text1: 2.1,2.2,2.3 crosystems Design and Fabrica Molecular Theory of Matter and	ors, Micro actuation, MEMS 3,2.4,2.5,2.6 ation: Introduction, Atomic	08 hrs with Micro Structure of
Teaching Learning Method: RBT Level: Working Principles of Micros actuators, Micro accelerometers Engineering Science for Mic Matter, Ions and Ionization M Electrochemistry.Text1: 3.1,3.	Chalk and talk method, Animat L1, L2, L3 Module 2 systems: Introduction, Microsense s, Microfluidics.Text1: 2.1,2.2,2.3 crosystems Design and Fabrica Molecular Theory of Matter and	ors, Micro actuation, MEMS 3,2.4,2.5,2.6 ation : Introduction, Atomic Intermolecular Forces, Pla	08 hrs with Micro Structure of sma Physics,
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4. U 5. K Sugge Text 1 1. T Refer 1. 2. 3. Activit 1: Deve probler CO1 CO2	Jnders <u>Know</u> ested J Book: Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra	tand d variou Learn n Hsu, Books s H G nger, 2 pKum gage I ng Liu red Le nini pr PO2 2 3	esign o s appli ing Ro , MEM : atzen, 2015. ar Bha Learnin , Foun arning ojects PO3 3	of scali cation cation source IS and Volke attachan g. dation g (Sugg and Fin	ing fac areas, es: Micros or Saile rya, Br s of M gested nal yea	tors in <u>mecha</u> systen e, Jurg rajesh <u>EMS,</u> <b>Activ</b> ar proj	n MEN anical ns: De gLeuth Kum Pears ities it jects u CO-I	MS dev packa esignar nold, 1 ar Ka on Ed n Clas sing M PO M	vices. <u>uging 1</u> ndMan Micros ushik,	for ME nufactur and Na Micro cactical compo	MS dev re,1 st Ed no Fabr electror <b>Based</b> onents t	ices. d, Tata rication nechani learnin o addre	: Tool : ical Sys ng ss the re PSO1 2 3	sand Pi stems (1 eal-wor PSO2 3 3	MEMS), ld
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4. U 5. K Sugge Text 1 1. T Refer 1. 2. 3. Activit 1: Deve probler CO1 CO2	Jnders <u>Know</u> ested J Book: Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra Tai-Ra	tand d variou Learn n Hsu, Books s H G nger, 2 pKum gage I ng Liu red Le nini pr PO2 2 3	esign o s appli ing Ro , MEM : atzen, 2015. ar Bha Learnin , Foun arning ojects PO3 3	of scali cation cation source IS and Volke attachan g. dation g (Sugg and Fin	ing fac areas, es: Micros er Saile rya, Bi s of M gested nal yea PO5	tors in <u>mecha</u> systen e, Jurg rajesh <u>EMS,</u> <b>Activ</b> ar proj	n MEN anical ns: De gLeuth Kum Pears ities it jects u CO-I	MS dev packa esignar nold, 1 ar Ka on Ed n Clas esing M	vices. <u>uging 1</u> ndMan Micros ushik,	for ME nufactur and Na Micro cactical compo	MS dev re,1 st Ed no Fabr electror <b>Based</b> onents t	ices. d, Tata rication nechani learnin o addre	: Tool : ical Sys ng ss the re PSO1 2 3	sand Pi stems (1 eal-wor PSO2 3 3	MEMS), ld

	COMMUNICATI	ON ENGINEEF	RING	
Course Code:	21ECT605	1	<b>CIE Marks:</b>	50
Teaching Hours/Week (L:T:P		-	SEE Marks:	50
Total Hours of Pedagogy:	39		Total Marks:	100
Credits:	03		Exam Hours:	03
Course objectives:				1
1. Describe essential elements	of an electronic com	munication system	m.	
2. Understand Amplitude, Freq		•		on.
3. Define the sampling theorem	and methods to gen	erate pulse modu	ilations.	
4. Learn the various methods o	f digital modulation	techniques and co	ompare the differen	t schemes.
5. Introduce the basic concepts				
6. Understand the basic concep		llular communica	ations.	
	Module-1			<b>08 Hrs</b>
Introduction to Electronic	<b>Communications:</b>	Historical pers	pective, Electroma	gnetic frequency
spectrum, Signal and its rep	resentation, Elemen	nts of electronic	c communications	system, primary
communication resources, sign	nal transmission con	ncepts, Analog an	nd digital transmis	sion, Modulation,
Concept of frequency translation	on, Signal radiation a	and propagation (	Text 1: 1.1 to 1.10)	
Teaching Learning Method:		1 1 0	,	
RBT Level:		· · · · · · · · · · · · · · · · · · ·	Signals and systems	
	RBT Level: L1, L2			
	Module-2	-,		08 Hrs
Amplitude Modulation Tech	niques: Types of an	alog modulation	, Principle of ampl	itude modulation,
AM power distribution, Limita				
Angle Modulation Technique				Concepts. Theory
of phase modulation (TEXT1:		10 1110 danamon, 1		concepts, meory
<b>Teaching Learning Method:</b>	Chalk and talk met	hod/Power point	presentation	
<b>RBT Level:</b>			VSB modulation t	echniques and
	comparison.			
	RBT Level: L1, L2	2, L3		
	Module-3			08 Hrs
Sampling Theorem and Pulse	<b>Modulation Techn</b>	iques: Digital Ve	rsus Analog Transm	issions, Sampling
Theorem, Classification of puls	e modulation technic	ques, PAM, PWM	I, PPM, PCM, Quar	tization of signals
(TEXT 1: 7.2 to 7.8)				
<b>Teaching Learning Method:</b>	Chalk and talk met	hod		
<b>RBT Level:</b>			and Delta Modulat	ion
	RBT Level: L1, L2			
	Module-4			08 Hrs
Digital Modulation Techniqu	es: Types of digital ]	Modulation, ASK	, FSK, PSK, QPSK	L. (TEXT 1: 9.1 to
9.5)	-		-	
Information Theory, Source a	and Channel Codin	<b>g:</b> Information. F	Entropy and its prop	erties, Shannon
Hartley Theorem, Objectives of		0		
	-	-	=	-
Channel coding theorem Error	Control and Codino			
Channel coding theorem, Error	Control and Coding	. [ ICXII. 10.1,10	.2, 10.11.2, 11.1 10	11.3, 11.8, 11.9,
11.12]	-			11.3, 11.8, 11.9,
_	Chalk and talk met			11.3, 11.8, 11.9,

Self-study topics: Quadrature Amplitude Modulation, Cor Digital Modulation	nparison of
techniques.	
RBT Level: L1, L2, L3	

#### Module-5

07 Hrs

**Evolution of wireless communication systems:** Brief History of wireless communications, Advantages of wireless communication, disadvantages of wireless communications, wireless network generations, Comparison of wireless systems, Evolution of next generation networks, Applications of wireless communication (TEXT 2: 1.1 to 1.7)

**Principles of Cellular Communications:** Cellular terminology, Cell structure and Cluster, Frequency reuse concept, Cluster size and system capacity, Method of locating cochannel cells, Frequency reuse distance (TEXT 2: 4.1 to 4.7)

<b>Teaching Learning Method:</b>	Chalk and talk method/Power point presentation
<b>RBT Level:</b>	Self-study topics: Basic propagation mechanisms, Multipath fading.
	RBT Level: L1, L2, L3

### **Course outcomes:**

#### At the end of the course the student will be able to:

CO1. Describe the scheme and concepts of radiation and propagation of communication signals through air.

CO2. Understand the AM and FM modulation techniques and represent the signal in time and frequency domain relations.

CO3. Understand the process of sampling and quantization of signals and describe different methods to generate digital signals.

CO4. Describe the basic digital modulation techniques, channel capacity, source coding technique and the channel coding.

CO5. Compare the different wireless communication systems and describe the structure of cellular Communication.

# Suggested Learning Resources:

**Text Books:** 

1: T L Singal, Analog and Digital Communications, McGraw Hill Education (India) Private Limited, 2012, 0-07-107269-1

**2:** T L Singal, Wireless Communications, McGraw Hill Education (India) Private Limited, 2016, ISBN:0-07-068178-3.

### Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Wherever necessary MatLab/Labview tools must be used.

1.Write Matlab Code for the following circuits, observe the waveform

i. AM, FM, QPSK, BPSK, TDM, PWM etc Generation and Demodulation.

### **CO-PO Mapping**

	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	3	3	3		2			1	1	1			1	1	1
CO2	3	3	3		3			1	1				1	1	1
CO3	3	3	3		1			1	1				1	1	1
CO4	3	3	3		1			1	1				1	1	1
CO5	3	3	3										1	1	1

High-3, Medium-2, Low-1

	MICROCONTROI	LLERS	
Course Code:	21ECT6052	CIE Marks:	50
Teaching Hours/Week (L:T:P	<b>:S):</b> 3:0:0	SEE Marks:	50
<b>Total Hours of Pedagogy:</b>	39	<b>Total Marks:</b>	100
Credits:	03	<b>Exam Hours:</b>	03
Course objectives:			
This course will enable studen	its to:		
• Understand the difference bet	ween a microprocessor and a	a microcontroller and embed	dded
microcontrollers.			
• Familiarize the basic architect	ure of 8051 micro controller		
Program 8051microprocessor	using Assembly Level Lang	uage and C.	
• Understand the interrupt syste	m of 8051 and the use of int	errupts.	
• Understand the operation and	use of inbuilt Timers/Counter	ers and the Serial port of 80	51.
• Interface 8051 to external men	nory and I/O devices using i	its I/O ports.	
	Module-1		08 hrs
8051 Microcontroller: Micr	roprocessor Vs Microcon	ntroller, Embedded Sys	tems, Embedded
Microcontrollers, 8051 Archited	cture- Registers, Pin diagram	n, I/O ports functions, Interr	nal Memory
organization. External Memory	(ROM & RAM) interfacing	·	
Text2 : Chapter 1 section 1.1 to	1.3, chapter 3 sections 3.1 t	to 3.3	
<b>Teaching Learning Method:</b>	Chalk and talk method, Por	wer Point Presentation,	
RBT Level:	L1, L2, L3		
	Module-2		08 hrs
8051 Instruction Set: Addressin	ng Modes, Data Transfer ins	tructions, Arithmetic instruc	ctions, Logical
instructions, Bit manipulation in	•		
loops) to use these instructions.			× ×
Text2 : Chapter 5, chapter 6, c			
Teaching Learning Method:	Chalk and talk method, Po	wer Point Presentation	
RBT Level:	L1, L2, L3		
	Module-3		08 hrs
8051 Jump and Call instructi		and Call Instructions. Ca	
instructions. Assembly languag	-		
8051 Programming in C: Data		• •	
Operations in C.	types and time delay in 000	r e, r e programming in e	oor e, logical
<b>Text2 :</b> chapter 8 section 8.1 to	8.4 Text1 $\cdot$ chapter 7 section	n 7 1 to 7 3	
Teaching Learning Method:	Chalk and talk method, Por		
RBT Level:	L1, L2, L3	wei i onit i resentation	
KDI Level.	Module-4		08 hrs
8051 Timers and Serial Port 803		paration and A gamply lang	
	1		uage programming
to generate a pulse using Mode			$0 \min \mathbf{D} \mathbf{S} 2 2 2$
8051 Serial Communication- B			-
signals, Simple Serial Port prog	ramming in Assembly and C	to transmit a message and	to receive data
serially.			

<b>Text1:</b> Chapter 9 section 9.1 Cl	hapter 10 section 10.1 to 10.5						
<b>Teaching Learning Method:</b>	Chalk and talk method, Power Point Presentation,						
<b>RBT Level:</b>	L1, L2, L3						
	Module-5	08 hrs					
8051 Interrupts and Interfacing	Applications.8051 Interrupts. 8051 Assembly language	e programming to					
	using a switch, 8051 C programming to generate a square						
-	. Interfacing 8051 to ADC-0804, DAC, LCD and Steppe						
8051 Assembly and C language							
	and 11.2 Chapter 13 section 13.1 to 13.2, chapter 12 sec	ction 12.1. chapter					
17 section 17.2							
Teaching Learning Method:	Chalk and talk method, Power Point Presentation						
RBT Level:	L1, L2, L3						
Course outcomes:	L1, L2, L3						
At the end of the course, the s	tudent will be able to:						
,	between Microprocessors & Microcontrollers, Arch	itecture of 8051					
1	8051 to external memory and instruction set of 8051.						
, e	level programs using the 8051-instruction set.						
CO3. Develop 8051 Assembly	C language program to generate timings and waveform	using 8051 timers					
to send & receive serial data us	ing 8051 serial ports.						
	/ C language programs to generate square wave on 8051	I/O port pin using					
1 0	end & receive serial data using 8051 serial port.						
* *	ral devices to 8051 using I/O ports.						
Suggested Learning Resource	S:						
<b>Text Books:</b> <b>1: Kenneth J.</b> Ayala, "The	8051 Microcontroller", Kenneth J Ayala, 3rd Edition, T	Thomson/Congogo					
Learning.	8051 Microcontroller, Kenneth J Ayala, 51t Edition, 1	nomson/Cengage					
0	, Janice Gillespie Mazidi and Rollin D. McKir	ulay. "The 8051					
·	Systems – using assembly and C", PHI, 2006 / Pearson,						
<b>Reference Books:</b>	······································						
1. "The 8051 Micro controller I	Based Embedded Systems", Manish K Patel, McGraw H	ill, 2014, ISBN:					
978-93-329-0125-4.							
	are, Programming, Interfacing and System Design", Raj	Kamal, Pearson					
Education, 2005.							
Web Links: https://swayam.go							
	gested Activities in Class)/ Practical Based learning						
Activity 1:							
Activity 2: Activity 3:							
Activity 5.							
CO-PO Mapping							

		P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO	1	3	3	3					3	1	2		1	1	2	3
CO	2	2	3	3		3			3	1	2		1	1	2	3
CO	3	2	3	3		3			3	1	2		1	1	2	3
CO	4	2	3	3		3			3	1	2		1	1	2	3
CO	5	2	3	3	2	3			3	1	2		1	1	2	3

High-3, Medium-2, Low-1

	BASIC VLSI DES	IGN						
Course Code:	21ECT6053	<b>CIE Marks:</b>	50					
<b>Teaching Hours/Week (L:T:P</b>		SEE Marks:	50					
Total Hours of Pedagogy:	39	Total Marks:	100					
Credits:	03	Exam Hours:	03 hrs					
Course objectives:								
1. Impart knowledge of MOS to								
2. Impart knowledge on archite		ce trade-offs involved in desig	ning and					
realizing the circuits in CMOS	65							
3. Cultivate the concepts of sub								
4. Demonstrate the concepts of			00 11					
	Module-1		08 Hrs					
Introduction: A Brief History		•	Characteristics,					
Nonideal I-V Effects, DC Trans								
Fabrication: nMOS Fabricatio	-	I process, N-well process, Twi	n tub process],					
BiCMOS Technology (1.7, 1.8,	,							
Teaching Learning Method:Chalk and talk method, YouTube videos, Power point presentation								
<b>RBT Level:</b>	-							
	Module-2		08 Hrs					
MOS and BiCMOS Circuit D			-					
Basic Circuit Concepts: Sheet I	Resistance, Area Capacitance	s of Layers, Standard Unit of (	Capacitance,					
Some Area Capacitance Calcul	ations, Delay Unit, Inverter D	elays, Driving Large Capaciti	ve Loads					
(3.1 to 3.3, 4.1, 4.3 to 4.8 of TE	EXT1).							
Teaching Learning Method:	Chalk and talk method/Pow	er point presentation						
RBT Level:	RBT Level: L1, L2, L3		00 11					
Sealing of MOS Civersity Sea	Module-3	for Device Porene store	08 Hrs					
Scaling of MOS Circuits: Sca								
Subsystem Design Processes: S		_						
Illustration of the Design Proc	0,00	an ALU Subsystem, The Ma	inchester Carry					
chain and Adder Enhancement	-							
(5.1, 5.2, 7.1, 7.2, 8.2, 8.3, 8.4.	1, 8.4.2 of TEXT1).							
<b>Teaching Learning Method:</b>		Tube videos, Power point pres	sentation					
<b>RBT Level:</b>	RBT Level: L1, L2, L3		-					
	Module-4		08 Hrs					
Subsystem Design: Some Arch		c, Gate (restoring) Logic, Pari	ty Generators,					
Multiplexers, The Programmab	le Logic Array (PLA)							
(6.1 to 6.3, 6.4.1, 6.4.3, 6.4.6 of	f TEXT1).							
FPGA Based Systems: Introdu	action, Basic concepts, Digita	l design and FPGAs, FPGA ba	ased System					
design, FPGA architecture, Phy	vsical design for FPGAs (1.1	to 1.4, 3.2, 4.8 of TEXT3).						
<b>Teaching Learning Method:</b>		Tube videos, Power point pres	sentation					
<b>RBT Level:</b>	RBT Level: L1, L2, L3							
	Module-5		07 Hrs					

Memory, Registers and Aspects of system Timing: System Timing Considerations, Some commonly used Storage/Memory elements (9.1, 9.2 of TEXT1).

Testing and Verification: Introduction, Logic Verification, Logic Verification Principles,

Manufacturing Test Principles, Design for testability (12.1, 12.1, 12.3, 12.5, 12.6 of TEXT 2).

Teaching Learning Method:Chalk and talk method/Power point presentation**RBT Level:**RBT Level: L1, L2, L3

**Course outcomes:** 

## At the end of the course the student will be able to:

CO1. Demonstrate understanding of MOS transistor theory, CMOS fabrication flow and technology scaling.

CO2. Draw the basic gates using the stick and layout diagrams with the knowledge of physical design aspects.

CO3. Interpret Memory elements along with timing considerations.

CO4. Demonstrate knowledge of FPGA based system design.

CO5. Interpret testing and testability issues in VLSI Design and analyse CMOS subsystems.

#### Suggested Learning Resources: Text Books:

1: "Basic VLSI Design"- Douglas A Pucknell & Kamran Eshraghian, PHI, 3rd Edition.

**2:** "CMOS VLSI Design- A Circuits and Systems Perspective", Neil H E Weste, David Harris, Ayan Banerjee, 3rd Edition, Pearson Education.

**3:** "FPGA Based System Design", Wayne Wolf, Pearson Education, 2004, Technology and Engineering.

### Web Links:

https://nptel.ac.in/courses/117101058

https://nptel.ac.in/courses/117106093

# Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Wherever necessary Cadence/Synopsis/Menta Graphics tools must be used.

1.Write Verilog Code for the following circuits and their Test Bench for verification, observe the waveform and synthesize the code with technological library with given Constraints*. Do the initial timing verification with gate level simulation.

i. An inverter

ii. A Buffer

iii. Transmission Gate

iv. Basic/universal gates

v. Flip flop -RS, D, JK, MS, T

vi. Serial & Parallel adder

vii. 4-bit counter [Synchronous and Asynchronous counter]

2. Design an op-amp with given specification* using given differential amplifier Common source and Common Drain amplifier in library** and completing the design flow mentioned below:

a. Draw the schematic and verify the following

i) DC Analysis

ii) AC Analysis

iii) Transient Analysis

b. Draw the Layout and verify the DRC, ERC

c. Check for LVS

d. Extract RC and back annotate the same and verify the Design

	CO-PO Mapping														
	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	<b>PSO3</b>
CO1	3	3	3		2								1	1	1
CO2	3	3	2										1	1	1
CO3	3	2	1										1	1	1
CO4	3	3	2										1	1	1
CO5	3	2	3										1	1	1
High-3	ligh-3, Medium-2, Low-1														

ELI	ECTRONIC	S CIRCUITS W	/ITH VERILOG	
Course Code:		CT6054	<b>CIE Marks:</b>	50
Teaching Hours/Week (L:T:P		P :: 3:0:0)	SEE Marks:	50
Total Hours of Pedagogy:	39		Total Marks:	100
Credits:	03		Exam Hours:	03
Course objectives:	05		Exam mours.	05
1. To understand the basic Veril	og HDL desi	an flow		
2. To understand the basic Veril	0	0		
3. To describe the simple logic of			evel and behavioural le	vel modelling
4. To model digital systems usin	U	. 0	-	ver moderning.
	Modu			08 Hrs
Overview of Digital Design w			of CAD, emergence of	
flow, why Verilog HDL?, trends	_			
Hierarchical Modelling Conc		,	un design methodology	differences between
_				
modules and module instances,	-			lext I)
Teaching Learning Method:			er point presentation	
<b>RBT Level:</b>	RBT Level:			00 11
	Modu	-		08 Hrs
Basic Concepts: Lexical conve				
Modules and Ports: Module de	efinition, port	declaration, cor	necting ports, hierarchie	cal name referencing.
(Text 1)				
<b>Teaching Learning Method:</b>	Chalk and ta	alk method, Pow	er point presentation	
<b>RBT Level:</b>	<b>RBT</b> Level:	L1, L2, L3		
	Modu	le-3		08 Hrs
Gate-Level Modeling: Modeling	ng using basi	c Verilog gate pi	rimitives, description of	and/or and buf/not
type gates, rise, fall and turn-of				
<b>Dataflow Modeling:</b> Continuou	-			ators, operands.
operator types. (Text 1)		is, actual specific		acors, operanas,
Teaching Learning Method:	<u>C1 11 1</u>			
RBT Level:	Challz and to	ally method Dow	er point presentation	
			er point presentation	
	RBT Level:	L1, L2, L3	er point presentation	08 Hrs
	RBT Level: Modu	L1, L2, L3 le-4		08 Hrs
Behavioral Description: Be	RBT Level: Modu havioral De	L1, L2, L3 le-4 scription Highl	ights, Structure of th	e HDL Behavioral
<b>Behavioral Description:</b> Be Description, Sequential Stateme	RBT Level: Modu havioral Des ents, IF States	L1, L2, L3 le-4 scription Highl ment, The case S	ights, Structure of th statement, Verilog cases	e HDL Behavioral and casez The wait-
<b>Behavioral Description:</b> Be Description, Sequential Stateme for Statement. The Loop Statem	RBT Level: Modu havioral Depents, IF Statem nent, For-Loc	L1, L2, L3 le-4 scription Highl ment, The case S	ights, Structure of th statement, Verilog cases	e HDL Behavioral and casez The wait-
<b>Behavioral Description:</b> Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2)	RBT Level: Modu havioral Des ents, IF States nent, For-Loc )	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop,	ights, Structure of th tatement, Verilog cases Verilog repeat, Verilog	e HDL Behavioral and casez The wait-
<b>Behavioral Description:</b> Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) <b>Teaching Learning Method:</b>	RBT Level: Modu havioral Des ents, IF States nent, For-Loc ) Chalk and ta	L1, L2, L3 <b>le-4</b> scription Highl ment, The case S op, While-Loop, alk method, Pow	ights, Structure of th statement, Verilog cases	e HDL Behavioral and casez The wait-
<b>Behavioral Description:</b> Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2)	RBT Level: Modu havioral De- ents, IF States nent, For-Loc Chalk and ta RBT Level:	L1, L2, L3 <b>le-4</b> scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3	ights, Structure of th tatement, Verilog cases Verilog repeat, Verilog	HDL Behavioral and casez The wait- forever (content with
Behavioral Description: Bei Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) Teaching Learning Method: RBT Level:	RBT Level: Modu havioral Desents, IF States nent, For-Loc Chalk and ta RBT Level: Modu	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5	ights, Structure of th statement, Verilog cases Verilog repeat, Verilog rer point presentation	HDL Behavioral and casez The wait- forever (content with 07 Hrs
Behavioral Description: Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) Teaching Learning Method: RBT Level: Structural Description: Highlight	RBT Level: Modu havioral De- ents, IF Statement, For-Loc Chalk and ta RBT Level: Modu hts of Structu	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5 ral Description,	ights, Structure of th statement, Verilog cases Verilog repeat, Verilog rer point presentation	HDL Behavioral and casez The wait- forever (content with 07 Hrs
Behavioral Description: Bei Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) Teaching Learning Method: RBT Level:	RBT Level: Modu havioral De- ents, IF Statement, For-Loc Chalk and ta RBT Level: Modu hts of Structu	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5 ral Description,	ights, Structure of th statement, Verilog cases Verilog repeat, Verilog rer point presentation	HDL Behavioral and casez The wait- forever (content with 07 Hrs
Behavioral Description: Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) Teaching Learning Method: RBT Level: Structural Description: Highlight	RBT Level: Modu havioral Desents, IF Statement, For-Loco Chalk and ta RBT Level: Modu hts of Structur ple 4.9) (Text	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5 ral Description, 2)	ights, Structure of th Statement, Verilog cases Verilog repeat, Verilog rer point presentation Organization of Structur	HDL Behavioral and casez The wait- forever (content with 07 Hrs ral Description
Behavioral Description: Bei Description, Sequential Stateme for Statement. The Loop Statemerespect to Verilog only) (Text 2) Teaching Learning Method: RBT Level: Structural Description: Highligh Binding (4.1, 4.2, 4.3 till example	RBT Level: Modu havioral Desents, IF Statement, For-Loco Chalk and ta RBT Level: Modu hts of Structur ple 4.9) (Text	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5 ral Description, 2)	ights, Structure of th Statement, Verilog cases Verilog repeat, Verilog rer point presentation Organization of Structur	HDL Behavioral and casez The wait- forever (content with 07 Hrs ral Description
Behavioral Description: Be Description, Sequential Stateme for Statement. The Loop Statem respect to Verilog only) (Text 2) Teaching Learning Method: RBT Level: Structural Description: Highligh Binding (4.1, 4.2, 4.3 till examp Tasks and Functions: Different	RBT Level: Modu havioral Desents, IF Statement, For-Loco Chalk and ta RBT Level: Modu hts of Structure ble 4.9) (Text hts between	L1, L2, L3 le-4 scription Highl ment, The case S op, While-Loop, alk method, Pow L1, L2, L3 le-5 ral Description, 2) tasks and function	ights, Structure of th Statement, Verilog cases Verilog repeat, Verilog rer point presentation Organization of Structur	HDL Behavioral and casez The wait- forever (content with 07 Hrs ral Description

#### **Course outcomes:**

# At the end of the course the student will be able to:

CO1. Understand the Verilog HDL design flow.

CO2. Describe the basic concepts of Verilog HDL programming

CO3. Design of digital electronics circuits using dataflow, behavioural, gate-level, and structural modelling.

CO4. Design complex digital circuits using advanced Verilog concepts.

# Suggested Learning Resources:

# **Text Books:**

1: "Verilog HDL: A Guide to Digital Design and Synthesis", Samir Palnitkar, Pearson education, Second edition.

2: "HDL programming (VHDL and Verilog)", Nazeih M Botros, John Wiley India Pvt. Ltd., 2008.

## Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Wherever necessary Xilinx/Model sim, Questa tools must be used.

**1.**Write Verilog Code for the following circuits and their Test Bench for verification, observe the waveform and synthesize the code with technological library with given Constraints*. Do the initial timing verification with gate level simulation.

i. An inverter

ii. A Buffer

iii. Transmission Gate

iv. Basic/universal gates

v. Flip flop -RS, D, JK, MS, T

vi. Serial & Parallel adder

vii. 4-bit counter [Synchronous and Asynchronous counter]

### **CO-PO Mapping**

	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1	CO1	3	3	3		2								1	1
CO2	CO2	3	3	2										1	1
CO3	CO3	3	2	1										1	1
<b>CO4</b>	<b>CO4</b>	3	3	2										1	1

High-3, Medium-2, Low-1

SENSORS & ACTUATORS							
Course Code:	21ECE6055	<b>CIE Marks:</b>	50				
Teaching Hours/Week (L:T:P:S):	3:0:0:0	SEE Marks:	50				
Total Hours of Pedagogy:	39	<b>Total Marks:</b>	100				
Credits:	03	<b>Exam Hours:</b>	03				

#### **Course objectives:**

• To provide the fundamental knowledge about sensors and measurement system.

• To impart the knowledge of static and dynamic characteristics of instruments and understand the factors in selection of instruments for measurement.

• To discuss the principle, design and working of transducers for the measurement of physical time varying quantities.

• Understand the working of various actuators suitable in industrial process control systems.

• Understand the principle and application of smart sensors.

#### Module-1

**Sensors and measurement system:** Sensors and transducers, Classifications of transducers-primary & secondary, active & passive, analog and digital transducers. Smart sensors.

**Measurement:** Definition, significance of measurement, instruments and measurement systems. mechanical, electrical and electronic instruments. Elements of generalized measurement system with example. Input-output configuration of measuring instruments and measurement systems, methods of correction for interfering and modifying inputs.

Teaching Learning Method:	Chalk and talk method, PowerPoint Presentation, More examples relating
	to applications
RBT Level:	L1, L2, L3

**Static and Dynamic Characteristics**: Static calibration and error calibration curve, accuracy and precision, indications of precision, static error, scale range and scale span, reproducibility and drift, repeatability, signal to noise ratio, sensitivity, linearity, hysteresis, threshold, dead zone and dead time, resolution, signal to noise ratio, factors influencing the choice of transducers/instruments. Dynamic response – Dynamic characteristics, Transfer function of generalized first order system, time constant. Transfer function of generalized second order system, natural frequency and Damping ratio.

the characteristics of sensors, More examples relating to applications	<b>Teaching Learning Method:</b>	Chalk and talk method, Power point presentation, VI Lab to demonstrate
		the characteristics of sensors, More examples relating to applications
KDI LEVEL. L1, L2, L3	<b>RBT Level:</b>	L1, L2, L3

Module-3

**Measurement of Temperature**: RTD, Thermistor, Thermocouple, laws of thermocouple, Thermopile, AD590.

**Measurement of Displacement**: Introduction, Principles of Transduction, Variable resistance devices, variable Inductance Transducer, Variable Capacitance Transducer, Hall Effect Devices, Proximity Devices, Digital Transducer.

<b>Teaching Learning Method:</b>	Chalk and talk method, PowerPoint Presentation, Virtual instrumentation
	Lab to demonstrate the characteristics of sensors
<b>RBT Level:</b>	L1, L2, L3

Module-4

**Measurement of Strain**: Introduction, Types of Strain Gauges, Theory of operation of resistance strain gauges, Types of Electrical Strain Gauges –Wire gauges, unbounded strain gauges, foil gauges, semiconductor strain gauges (principle, types & list of characteristics only), Strain gauge Circuits – Wheatstone bride circuit, Applications.

**Measurement of Force & Torque:** Introduction, Force measuring sensor –Load cells – column types devices, proving rings, cantilever beam, pressductor. Hydraulic load cell, electronic weighing system. Torque measurement: Absorption type, transmission type, stress type & deflection type.

<b>Teaching Learning Method:</b>	Chalk and talk method, PowerPoint Presentation, More examples relating
	to applications
RBT Level:	L1, L2, L3
	Modulo 5

Module-5

Actuators and process control system: Introduction. Block diagram and description of process control system with an example. Introduction, Block diagram of Final control operation, Signal conversions analog, digital, pneumatic signal. Actuators, Control elements.

**Electrical actuating systems:** Solid-state switches, Solenoids, Electric Motors- Principle of operation and its application: D.C motors, AC motors, Synchronous Motor, Stepper motors.

**Pneumatic Actuators**: Principle and working of pneumatic actuators. (Numerical problems on the topic).

Hydraulic Actuators: Principle and working of Hydraulic actuators. (Numerical problems on the topic).

<b>Teaching Learning Method:</b>	Chalk and talk method, Power point presentation, More examples relating
	to applications
<b>RBT Level:</b>	L1, L2, L3

### **Course outcomes:**

### At the end of the course the student will be able to:

**CO1:** Discuss the fundamental concepts related to sensors and measurement, functional elements of measurement system, I/O Characteristics of measurement system.

**CO2:** Interpret and analyse the static and dynamic characteristics of instruments.

**CO3:** Elucidate the working principle and usage of different transducers for temperature, displacement and level measurement.

**CO4:** Discuss the principle and working of different types of actuators used in industrial application.

**CO5:** Discuss the principle and working of strain, force and torque measurement

### Suggested Learning Resources:

### **Text Books:**

1.Electrical and Electronic Measurements and Instrumentation, A K Sawhney, 17th Edition, (Reprint 2004), Dhanpat Rai & Co. Pvt. Ltd., 2004.

2. Instrumentation: Devices and Systems, C S Rangan, G R Sarma, V S V Mani, 2nd Edition (32 Reprint), McGraw Hill Education (India), 2014.

3. Process Control Instrumentation Technology by C D Johnson, 7th Edition, Pearson Education Private Limited, New Delhi 2002.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning Activity 1: Activity 2: Activity 3:

	P01	P02	PO3	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1															
CO2															
CO3															
<b>CO4</b>															
CO5															
CO5															

						V	/LSI I	LAB						
Course	Code				2	1ECL	606			CIE	Marks	50		
Teachir	ng Hours	s/Wee	k (L:	<b>T: P:</b>	<b>S</b> ) 0	:0:2:0				SEE	Marks	50		
Credits					01	L				Exan	1 Hours	03		
Course	objectiv	es:												
	ooratory													
	esign, m esign lay					•	OS di	gital c	ircuits					
	erform p			0			digita	al circi	uits					
	erform R	-					-			ign.				
Sl. No.				Exp	erime	ents								
1	DC, Tr	ansier	nt anal	ysis o	f CM0	OS log	gic-Ur	niversa	l gates	schema	atic			
2	DC, Tr	ansier	nt anal	ysis o	f CM	OS ful	l adde	er sche	matic					
3				•						on gate	s schem	atic		
4	DC, Tr				f Sequ	ential	circui	its sch	ematic					
		Clocke Aaster			e Trigg	pered	Regist	er						
5	DRC a			-			-		t					
6	DRC a	nd LV	'S ana	lysis o	of Con	nmon	Sourc	e Am	olifier I	Layout				
7	DRC a	nd LV	'S ana	lysis o	of Con	nmon	Drain	Ampl	lifier La	ayout				
8	DRC a	nd LV	'S ana	lysis o	of Diff	erenti	al Am	plifie	r Layou	ıt				
09	Synthe	sis and	d Sim	ulation	n of In	verter	using	g Veril	og code	e				
10	Synthe	sis and	d Sim	ulatio	n of B	uffer V	Verilo	g code	e					
11	Synthe	sis and	d Sim	ulatio	n of B	asic/U	Inivers	sal Ga	te using	g Verilo	og code			
12	Synthe	sis and	d Sim	ulatio	n of JH	K, MS	JK flij	p-flop	s using	Verilog	g code			
Course	outcom	es (Co	urse S	Skill S	Set):									
	completi				•									
	esign an Design an											mnlifie	er and	
	Differenti					) eneu	nts nk		1101, 00	minon	source a	mpiiik	a unu	
	erform A		0					-		•		esis co	nstrain	ts
	nd evalua Design a	0			-			1	0			Verilo	σHDI	
001.	Design		mului	com	omain	Jilui ui	nu seg	uentita	ii uigitu	il elleur	to using	venno	5 IIDD.	
						CO-	PO M	lappir	ng					
PC CO1	01 PO2	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO2														
CO3														
CO4	, Medium													

MINI PROJECT								
Course Code:	21ECM607	<b>CIE Marks:</b>	50					
Teaching Hours/Week (L:T:P:S):	0:0:2:0	<b>SEE Marks:</b>	50					
Total Hours of Pedagogy:	26	<b>Total Marks:</b>	100					
Credits:	02	Exam Hours:	03					

#### Course objectives: The student will be able to learn,

- 1. Identification of problem, formulation and methodology.
- 2. To gain technical knowledge by literature survey.
- 3. Justify the technical aspects with a comprehensive and systematic approach.
- 4. Engineering solutions to meet industrial and societal needs.

#### **Mini Project Guidelines:**

The project topic, title and synopsis have to be finalized and submitted to their respective internal guide(s). The detailed Synopsis (approved by the department Project Review Committee) has to be submitted during the 1st week after the commencement of 6th semester.

#### **Formation of Groups:**

Students are free to choose their project partners from within the programme or any other programme. The project work is to be carried out by a team of two to four students. Each student in the team must contribute towards the successful completion of the project.

The project may be carried out In-house / Industry / R & D Institution.

#### **Selection of Project Topic:**

The topics of the project work must be in the field of respective program. The projects as far as possible should have societal relevance with focus on sustainability.

#### **Course outcomes:**

### At the end of the course the student will be able to:

- **CO1** Acquire knowledge within the chosen domain.
- **CO 2** Usage of Tools based on the problem.
- **CO 3** Implement using resource management skills.
- CO 4 Demonstrate, Present and Report writing.
- **CO 5** Exhibit life -long learning & Professional ethics.

### Assessment Details (both CIE and SEE):

#### **CIE Assessment:**

The following are the weightings given for the various stages of the project. 20%

- 1. Identification of Problem and Introduction
- 20% 2. Literature Survey and Identifying Research Gap
- 3. Methodology, H/W & amp; S/W Specifications 20%
- 4. Design requirements and Specifications 20%
- 5. Presentation and Viva voce 20%

#### **SEE Assessment:**

The following are the weightages given during Viva Examination.

1. Written presentation of synopsis 10% 2. Presentation/Demonstration of the project 30% 3. Methodology and Experimental Results & Discussion 30% 4. Report 10% Viva Voce 20% 5.

COs **Mapping with Pos** 

CO1	PO1, PO2, PO5, PO7, PO8, PO9, PO10, PO11
CO2	PO1, PO2, PO5, PO9, PO10, PO11
CO3	PO1, PO2, PO3, PO4, PO5, PO6, PO7, PO8, PO9, PO10, PO11
CO4	PO1, PO2, PO5, PO6, PO8, PO9, PO10, PO11, PO12
CO5	PO1, PO2, PO5, PO8, PO10, PO11, PO12

COs	PO1	PO2	PO3	PO4	PO5	PO6	<b>PO7</b>	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2	-	-	2	-	2	1	1	1	1	-	3	2	-
CO2	1	1	-	-	3	-	-	-	2	1	1	-	2	2	1
CO3	1	1	3	3	2	1	1	1	1	1	1	-	-	2	2
CO4	1	1	-	-	1	1	-	3	3	1	2	3	2	2	1
CO5	2	2	-	-	1	-	-	3	-	1	2	3	1	2	3

High-3, Medium-2, Low-1

Semester VI

INNOVATION/ENTREPRENEURSHIP/SOCIETAL INTERNSHIP								
Course Code:	21ECI608	<b>CIE Marks:</b>	50					
Teaching Hours/Week (L:T:P:S):		SEE Marks:	50					
<b>Total Hours of Pedagogy:</b>		<b>Total Marks:</b>	100					
Credits:	3	<b>Exam Hours:</b>	3					

#### **Course objectives:**

- 1. Understand the process of applying engineering knowledge to produce product and provide services.
- 2. Explain the importance of management and resource utilization
- 3. Comprehend the importance of team work, protection of environment and sustainable solutions.
- 4. Imbibe values, professional ethics for life long learning.

#### Guidelines

**Research/Industrial Internship** - At the End of the sixth / Seventh semester (in two cycles to accommodate all the students of the University) Research/Industrial Internship shall be carried out – Based on industrial/Govt./NGO/MSME/Rural Internship/Innovation/Entrepreneurship. All the students admitted shall have to undergo a mandatory internship of 24 weeks during the vacation of VI/VII semesters. A University Viva-Voce examination shall be conducted during VII/VIII semester and the prescribed credit shall be included in VII/VIII semester. The internship shall be considered as a head of passing and shall be considered for the award of degree. Those, who do not take up/complete the internship shall be declared fail and shall have to complete during subsequent University examination after satisfying the internship requirements. Research internship Students have to take up research internships at Centers of Excellence (CoE) / Study Centers established in the same institute and /or out of the institute at reputed research organizations / Institutes. A research internship is intended to give you the flavour of current research going on on a particular topic/s. The internships serve this purpose. They help students get familiarized with the field, the skill needed the effort amount and kind of effort required for carrying out research in that field.

**Industry internships:** This is an extended period of work experience undertaken by university/Institute students looking to supplement their degree with professional development. The students are allowed to prepare themselves for the workplace and develop practical skills as well as academic ones. It also helps them learn to overcome unexpected obstacles and successfully navigate organizations, perspectives, and cultures. Dealing with "unexpected contingencies" helps students recognize, appreciate, and adapt to organization realities by tempering knowledge with practical constraints.

Those, who have not pursued /completed the internship will be declared as failed and have to complete during subsequent SEE examination after they satisfy the internship requirements.

Course outcomes: At the end of the course the student will be able to: CO1. Apply engineering and management principles CO2. Analyze real-time problems and suggest alternate solutions CO3. Communicate effectively and work.CO4. Imbibe the practice of professional ethics and need for lifelong learning.

	P01	P02	P03	P04	P05	P06	P07	P08	P09	PO 10	P011	P012	PSO1	PSO2	PSO3
CO1		2	3	2		2				1			3		2
CO2				3	2	2		1					1	1	2
CO3					1		2	3	3					2	2
<b>CO4</b>					1		3			2	3		2	3	2
CO5															



#### Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU -

560056.

(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

#### **Department of Electronics & Communication Engineering**

Ref. No: AIT /EC /BOS / 467 /2023-24

Date: 12-08-2023

**To** Dean (Academic) Dr Ambedkar Institute of Technology Bengaluru-56

Sir,

#### Sub: Regarding the details of the BOS meeting held on 12-08-2023

The External BOS 2023-24 meeting was held in blended mode in the department of the Electronics and communication Engineering and through Google meet link: https://meet.google.com/iun-vhbc-tfs on Saturday, 12-08-2023 10:30 am.

The BOS committee has approved the following:

- 1. NEP based Scheme and I & II semester syllabus of UG Courses of the 2023 Batch Students.
- 2. NEP based Scheme and III & IV semester syllabus of UG Courses of the 2022 Batch Students.
- 3. NEP Based Scheme and V & VI semester Syllabus of UG Courses of the 2021 Batch Students.
- 4. VII & VIII semester Syllabus of UG Courses of the 2020 Batch Students.
- 5. Skill Lab for 2023 batch students.
- 6. Scheme and Syllabus of I and II-year PG course.
- 7. The List of BOE members.
- 8. The list of Valuers / Examiners.

Thanking you

Taldlipa V Mand

CHAIRMAN BOS Dept. of ECE

Dept. of Electronics and Communication Engg. Dr. Ambedkar Institute of Technology Bengaluru - 560056

#### Enclosures:

- 1. List of Members of BOS.
- 2. Curriculum Design -UG
- 3. Minutes of the BOS Meeting.
- 4. Scheme & Syllabus of I/II Semester Basic Electronics and Communication Engineering for the academic year 2023-24.
- 5. Scheme & Syllabus of 3rd and 4th Semesters for the academic year 2023-24.
- 6. Scheme & Syllabus of 5th and 6th Semesters for the academic year 2023-24.
- 7. Scheme & Syllabus of 7th and 8th Semesters for the academic year 2023-24.
- 8. List of BOE Members.
- 9. List of valuers / Examiners.



# Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU -560056. (An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

#### **Department of Electronics & Communication Engineering**

## Members of BOS:

SI No.	CATEGORY	Nomination of the Committee	Name of the Person with Designation
1	Head of the Department	Chairperson	Dr. Mahalinga V Mandi, Dean (P&D), Professor & Head, Department of ECE, Dr. AIT, Bengaluru-56
<ul> <li>Faculty Members at Different Levels Bearing Different Specializations</li> </ul>		Member 1.	Dr. Umadevi H. Professor, Department of ECE, Dr. AIT, Bengaluru-56
	Different Levels Bearing	Member 2.	Dr. Ramesh S, Dean (Exam), Professor, Department of ECE, Dr. AIT, Bengaluru-56
		Member 3.	Smt. Sudha B S. Associate Professor, Department of ECE, Dr. AIT, Bengaluru-56
		Member 4.	Dr. Shivaputra Assistant Professor Department of ECE, Dr. AIT, Bengaluru-56
		Member 5.	Dr. Meenakshi.L.R. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56
		Member 6.	Mr. Mohan Kumar V Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56
		Member 7.	Dr. Jambunath S Baligar Associate Professor Department of ECE, Dr. AIT, Bengaluru-56
		Member 8.	Dr. Chetan. S Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56
3	Subject Experts from outside the College Nominated by Academic Council	Member 1.	Dr. Devendra Jalihal Professor, EEE department IIT Madras, Chennai-600 036



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		Member 2.	Prof. Santanu Mahapatra Professor, Department of Electronic Systems Engineering, Indian Institute of Science Bangalore, Bengaluru- 560012
		Member 3.	Dr. Mandeep Singh Professor, Department of ECE, NITK, Surathkal
		Member 4.	Prof. P.Nagaraju Associate Professor, Dept. of TCE, RVCE, Bengaluru-560 059
4	Expert from outside College, Nominated by Vice Chancellor (VTU)	VTU Nominee	Dr. Manajanaik N Professor, Department of ECE, UBDT, Davangere, Karnataka
	Representative from Industry /Corporate Sector/Allied area related to Placement Nominated by Academic council	Member 1.	Mr. Kubendra.K Senior Design Engineer VLSI Group, Samsung India,Outer ring Road, Near Marathahalli, Bengaluru
		Member 2.	Mr. Somshekar H Mobileum India Pvt ltd., Director of Engineering.
5		Member 3.	Mr. Sampath Kumar Srinivas Mitel, Senior Staff Software Engineer Manyata Tech Park, Bangalore
6	Post Graduate Meritorious alumnus nominated by Principal	Member	Mr. Premkumar M N Senior Manager, Intel, India Bengaluru

Davalipa V Mande

CHAIRMAN **BOS Dept. of ECE** HOD Dept. of Electronics and Communication Engg., Dr. Ambedkar Institute of Technology Bengaluru - 560056



Department of Electronics & Communication Engineering

# MINUTES OF THE MEETING OF THE BOARD OF STUDIES 2023-24

DATED: Saturday, 12th August 2023

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#### Department of Electronics & Communication Engineering

#### **BOS Meeting Notice**

Sub: Board of Studies Meeting is convened on 12-08-2023

With reference to the above subject, External Board of Studies Meeting of the department is convened on Saturday, the 12th August 2023 at 10:30 a.m. in Department of ECE for finalizing the scheme and syllabus of UG in B.E. (E & C) and PG, M.Tech in VLSI Design and Embedded Systems for the academic year 2023-24 with the following agenda.

#### Agenda:

- Approval of the NEP Scheme and Syllabus of 1st to 8th Semesters B.E (E &C) for the Batch-2023
- Approval of the NEP Scheme and Syllabus of 3rd to 8th Semester B.E(E & C) for the Batch -2022
- Approval of the NEP Scheme and Syllabus of 5th to 8th Semester B.E(E & C) for the Batch-2021
- Approval of the Scheme and Syllabus of 7th to 8th Semester B.E(E & C) for the Batch-2020
- 5. Approval of Basic IoT Skill Lab for the Batch-2023 students.
- Approval of the Scheme and Syllabus for the 1st and 2nd Semester PG for the Batch-2023
- 7. Approval of the Scheme and Syllabus for the 3rd and 4th Semester PG for the Batch-2022.
- 8. Approval of the courses for the Major, Minor Degree
- 9. Approval of List of Examiners



#### **Department of Electronics & Communication Engineering**

#### Minutes of Board of Studies (BOS) Meeting:

The Meeting of Board of Studies (BOS) for Department of Electronics and Communication Engineering was held on 12-08-2023 at 10:30 a.m. under the Chairmanship of the Dr. Mahalinga V. Mandi, Dean (P&D), Professor and Head, Department of Electronics and Communication Engineering in the department of Electronics and Communication engineering and through Google meet link: https://meet.google.com/iun-vhbc-tfs.

At the very outset, the Chairman welcomed all the Internal and External members of BOS to the meeting and gave a preliminary presentation on the agenda items with reference to the scheme and syllabus of UG and PG for the academic year 2023-24

The chairman along with BOS coordinators gave a detailed presentation of the courses to be offered to the students in both Core and Elective subjects in semester wise at the Under Graduate level and Post Graduate level, also briefed the members about the Curriculum Design of the Department for the UG and PG Courses.

#### PROCEEDINGS/RESOLUTIONS:

The following are the Suggestions of the members of BOS with reference to the presentations:

I and II semester for 2023 batch:

- Subject Expert Devendra Jalihal Suggested to reduce the syllabus for "Basic electronics" (Module 1) for ECE
   Sol. Internal BOS members clarified that most of the topics will be dealt up to Remembering & Understand level (L1, L2)
- Subject Expert Mandeep Singh suggested to include recent edition text books for the course Introduction to Electronics Engineering (22EST104C/204C).
   Sol. Recent edition text books prescribed for subject Introduction to Electronics Engineering (22EST104C/204C).

#### III and IV Semesters for 2022 batch:

 Subject Expert Devendra Jalihal suggested to rearrange the contents of the topic Fourier Transforms in the subject "Signals and Systems".
 Sal Table Equation Transformed as a statement of the subject "Signals and Systems".

Sol. Topic Fourier Transforms in the subject "Signals and Systems" is rearranged as per the suggestions.



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 Subject Expert Dr. Nagaraju P remarked regarding the IPCC subject Analog Electronic Circuits (21ECT303) that JFET experiment was added in practical component while only concepts of MOSFET were dealt in theory.

Sol. JFET experiments in practical component is replaced by MOSFET experiments.

- Subject Expert Dr. Nagaraju P suggested to reduce the contents of 7th and 8th experiments in Analog and Digital Electronics Lab (22ECL305).
   Sol. Redundant experiments are removed as per suggestions.
- Subject Expert Dr. Nagaraju P suggested to include Proportional controller concept in module 3 in the IPCC subject Modern Control Systems as these concepts were included in practical component.

Sol. Proportional Controller Concepts included in module 3.

#### V and VI Semesters for 2021 batch:

- Industry Expert Sampath Kumar Srinivas seek clarification regarding the duration for mini project.
- Industry Expert Sampath Kumar Srinivas suggested to include IPV6 concept in Computer Communication Networks (21ECT503).
   Sol. IPV6 concept included as per suggestion.
- Subject Expert Dr. Nagaraju P suggested to include recent edition books for the subject Microwave and Antenna.

Sol. Prescribed Textbooks updated to recent editions.

- Industry Expert Kubendra suggested to include RISC V concepts in Microprocessor and Microcontroller subject.
   Sol. RISCV concepts included as Module 4 and Module 5 in Microprocessor and Microcontroller subject.
- Subject Expert Dr. Nagaraju P suggested to include Embedded C experiments instead of Assembly Programs in the subject CO & ARM Processor.
   Sol. Assembly Programs replaced with embedded C programs.
- Subject Expert Dr. Nagaraju P suggested to update prescribed text books for the subject ANN Sol. Prescribed text books updated to recent editions.
- Discussed about the Scheme and syllabus of 7th and 8th semester for 2020 batch
- No comments on final year subjects, so retained same syllabus.
- Discussed about the Scheme and syllabus of 1st and 2nd year PG program.
- Subject Expert Devendra Jalihal remarked that the number of electives are more. Sol. PG coordinator clarified that scheme and syllabus is framed as per VTU guidelines.
- Subject Expert Dr. Nagaraju P suggested to include recent edition text books.
   Sol. Recent edition text books are prescribed.





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• The meeting was ended with vote of thanks by Dr. Mahalinga V. Mandi, Dean (P&D), Professor and Head, Department of ECE.

Finally, the BOS members approved the following after incorporating the suggested modifications

- Approved the Curriculum Design for the semesters I to VIII of UG Course for the students of the Batch 2023
- Approved the NEP Based Syllabus of Basic Electronics and Communication Engineering for the semesters I/II of UG Course for the academic year 2023-24.
- Approved the NEP Based Scheme and syllabus for semesters III and IV of UG Course for the academic year 2023-24.
- Approved the NEP Based Scheme and syllabus for semesters V and VI of UG Course for the academic year 2023-24.
- Approved the Scheme and syllabus for semesters VII and VIII of UG Course for the academic year 2023-24.
- Approved Basic IoT Skill Lab for 2023 batch students.
- Approved I and II-year scheme and syllabus of PG Course for academic year 2023-24.
- > Approved the courses for the Major, Minor Degree
- > Approved the List of BOE members.
- > Approved the list of Valuers / Examiners.

CHAIRMAN **BOS Dept. of ECE** 

#### **BOS Coordinators**

- 1. Prof. B. S. Sudha
- 2. Mr. Anand H D

Signatures Sudha , A. is (2) (202) (2) (202)



### Department of Electronics & Communication Engineering

# List of BOE Members:

SL. NO.	NAME AND ADDRESS			
1.	Dr. Mahalinga V. Mandi, Dean (P & D), Professor and Head, Department of E			
Exte	rnal BOE members:			
1.	Dr. Dinesh P., Professor and Dean, Department of ECE, DSCE, Bengaluru			
2.	Prof. Nagraju P, Associate Professor, Department of TCE, RVCE, Bengaluru			
3.	Dr. Rajeshwari Hegade, Professor and Head, Department of TCE, BMSCE, Bengaluru-19			
4.	Dr. Revanna, Associate Professor, Department of ECE, Govt. Engineering College, Ramanagara			
Inter	mal BOE Members:			
1.	Dr. Umadevi H., Professor			
2.	Smt. Sudha B. S., Associate Professor			
3.	Dr. Shivaputra, Assistant Professor			
4.	Smt. Meenakshi L. Rathod, Assistant Professor			
5.	Mr. Mohankumar V., Assistant Professor			
6.	Smt. Girija S., Assistant Professor			

Talipar nand. CHAIRMAN

BOHOD^{pt.} of ECE Dept. of Electronics and Communication Engg., Dr. Ambedkar Institute of Technology Bengaluru - 560056



# Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY

(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

# Department of Electronics & Communication Engineering

#### 12-08-2023

#### Attendance list:

SI. No	Position	Name	Signature with date	
1,	Chairman	Dr. Mahalinga V. Mandi Professor and Head Department of ECE, Dr. AIT, Bengaluru-56	ABSENT	
2.	VTU Nomince	<b>Dr. Manajanaik N</b> Professor, Department of ECE, UBDT, Davangere, Karnataka		
3.	External Subject Experts	1. Dr. Devendra Jalihal Professor, EEE department IIT Madras, Chennai-600 036	Pousert Online.	
		2. Dr. Santanu Mahapatra Professor, Department of Electronic Systems Engineering, Indian Institute of Science Bangalore,560012	ABSENT	
		3. Dr. Mandeep Singh Professor, Department of ECE, NITK, Surathkal	Paerent Online.	
		4. Dr. P. Nagaraju Associate Professor, Dept. of TCE, RVCE, Bengaluru-560 059	P. Wy F. 19/08/2023	
4.	Industry Expert	1. Mr. Kubendra K Senior Design Engineer VLSI Group, Samsung India, Outer ring Road, Near Marathahalli, Bengaluru	Present Online.	
		2. Mr. Somshekar H Mobileum India Pvt ltd., Director of Engineering.	ABSENT	
		3. Mr. Sampath Kumar Srinivas Mitel, Senior Staff Software Engineer Manyata Tech Park, Bangalore	S: Caph 1- 12/8/2023	

5.	Alumni with PG Degree		Premkumar M N ior Manager, Intel, India Bengaluru	ADSENT
6.	Internal Members	1.	Dr. Umadevi H. Professor, Department of ECE, Dr.AIT,	Hlund
			Bengaluru-56	12/8/2
		2.	<b>Dr. Ramesh S.</b> Professor, Dean (E) Department of ECE, Dr. AIT, Bengaluru-56	Qw12-8-23
		3.	Smt. Sudha B. S. Associate Professor, Department of ECE, Dr. AIT, Bengaluru-56	5-2010-8
		4.	<b>Dr. Shivaputra</b> Assistant Professor Department of ECE, Dr. AIT, Bengaluru-56	on Leave
		5.	Dr. Meenakshi L. R. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	le 12/08/20
		6.	Mr. Mohan Kumar V. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	Hulen 12/08/20
		7.	Dr. Jambunath S. Baligar Associate Professor Department of ECE, Dr. AIT, Bengaluru-56	Khr 12/0/23
		8.	Dr. Chetan S. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	alitan 212/81
7.	Student Representatives:	1.	NOgesh.N.V IDAZIECIZO	Yogeshu
		2.	Yalavathi.v IDA21 ECI68	Jalewathi N
		3.	Bhulini RR IDADDEC4D6	Jalewathi N Shuti: PR
		4.	LIKHITHA . B IDA20 EC066	Elite
		5.	Divyashree. K DA20EC 041	Dive

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6. Jagunthé. S IDA20EC053 fagit	iù
7. Studiu. Hosamani IDA22LV303	
8. Rachmi. R IDA22LVSOD	

Marahipa V. Non d Signature HOD, Dept. of ECE **BOS Chairman** HOD Dept. of Electronics and Communication En-Dr. Ambedkar Institute of Technology

Bengaluru - 560056

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